Ultrasonic Parking Distance Measurement ASSP

General Description

The NCV75215 ASSP is intended to operate with a piezoelectric ultrasonic transducer to provide time-of-flight measurement of an obstacle distance during vehicle parking. The high-sensitivity, low-noise operation allows detection from 0.25 m up to 4.5 m for a standard 75 mm pole. Actual minimum distance is determined by the length of reverberations. Under ideal conditions, with perfectly tuned and matched external circuitry, a minimum distance of 0.2 m is achievable. Actual detection range depends on a piezoelectric ultrasonic transducer and external analog parts.

The device drives the ultrasonic transducer with a programmable frequency via a transformer. The received echo is amplified and converted to a digital signal, filtered, detected and the magnitude is compared to a time-dependent threshold which is stored in an internal RAM. Distance to the obstacle is determined by the time measured from a transmission burst to echo recognition.

A bidirectional I/O Line is used to communicate with a master (ECU). The master issues I/O Line commands to the NCV75215 and data are reported back via the same line.

Features

- Measurement Distance Range from 0.25 m to 4.5 m (depends on External Parts)
- Acoustic Noise Monitoring
- Transducer Resonant Period Measurement
- Diagnosis of Transducer Performance
- Junction Temperature Monitoring and Thermal Shutdown
- Transducer Center Frequency Range from 35 to 90 kHz
- Direct and Indirect Measurement Modes
- EEPROM Memory for Configuration Setting and User Data
- Rx Gain Adjustable in 0.5 dB Steps in the Range from 50 to 110 dB
- Time-dependent Threshold Values for the Sensitivity Control
- Dynamic (Time-dependent) Gain Control
- Tx Current Range Adjustable from 50 mA to 350 mA
- Programmable Ultrasonic Burst Length
- On-chip Bidirectional I/O Line
- Small TSSOP16 Package
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable*
- These are Pb-free Devices

Typical Applications

- Automotive Park Assist
- Ultrasonic Distance Measurements



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TSSOP-16 CASE 948F

MARKING DIAGRAM

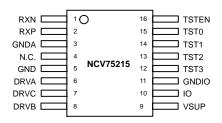
In accordance with:

US:

7620021 Mark Specifications – for ceramic, plastic and tape–automated bond packages

Europe: 16020 Standard Marking Specification

PIN CONNECTIONS



ORDERING INFORMATION

| Device | Package | Shipping [†] |
|-------------------|-----------|-----------------------|
| NCV75215DB001R2G* | TSSOP-16 | 4000 / Tape |
| | (Pb-Free) | & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

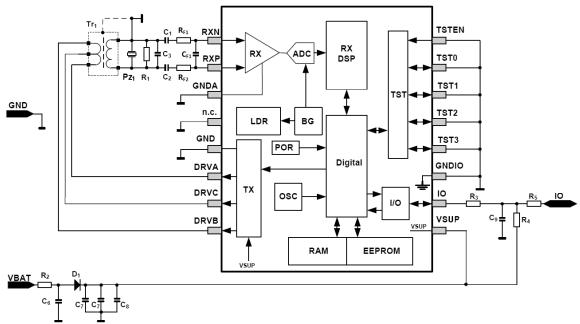


Figure 1. Application Schematic Diagram

Table 1. RECOMMENDED EXTERNAL COMPONENTS

| Name | Description | Typical Value | Units | Rating | Tolerance | Comment |
|------------|--|---------------|-------|--------|-----------|---|
| R1 | Resonator Damping | Optimal value | kΩ | | 5 % | Value depends on used transducer & transformer |
| R2 | Battery Filter Resistor | 100 | Ω | Note ⇒ | 5 % | Power rating according to required EMC robustness |
| R3 | I/O Line Protection | 470 | Ω | Note ⇒ | 5 % | It may be omitted but system ESD robust- ness is reduced Power rating according to required EMC robustness |
| R4 | I/O Line Pull Up | 10 | kΩ | 100 mW | 5 % | Optional. It is not used if I/O Line internal pull-up resistor is enabled (see Config RAM item IO_PUP_ENA) |
| R5 | I/O Line High Frequency Protection | 47 | Ω | Note ⇒ | 5 % | Optional It improves high frequency EMC robustness Power rating according to required EMC robustness |
| RF1 RF2 | Input EMC Filter Resistor (Note 1) | 100 | Ω | Note ⇒ | 5 % | Optional It improves high frequency EMC robustness Power rating according to required EMC robustness |
| C1 | Receiver Input Coupling | 680 | pF | 100 V | 10 % | |
| C2 | Receiver Input Coupling | 680 | pF | 100 V | 10 % | |
| C3 | Serial and Parallel Resonances Matching | optimal value | pF | 100 V | 5 % | Value depends on used transducer & transformer |
| CF1 | Input EMC Filter Capacitor (Note 1) | 10 | pF | 50 V | 10 % | Optional It improves high frequency EMC robustness |
| C6 | Battery Filter Capacitor | 100 | nF | 50 V | 10 % | |
| C7 | Tank Capacitor for Transmitting Current | 22 | μF | 35 V | 10 % | 2x ceramic type capacitor |

^{1.} Some of RF1, RF2 and CF1 components may be omitted. Use them according to required EMC robustness.

Table 1. RECOMMENDED EXTERNAL COMPONENTS (continued)

| Name | Description | Typical Value | Units | Rating | Tolerance | Comment |
|------|-----------------------------|--|-------|--------|-------------------------|---|
| C8 | VBAT HF Filter | 100 | nF | 50 V | 10 % | |
| C9 | I/O Line Capacitor | 330 | pF | 50 V | 10 % | Standard I/O Line slope (60 μs) IO_SLP_FAST = 0 |
| C9 | I/O Line Capacitor | 100 | pF | 50 V | 10 % | Fast I/O Line slope (20 μs) IO_SLP_FAST = 1 |
| Tr1 | Push-pull Transformer | Transducer specific | mH | 100V | 5% | |
| PZ1 | Ultrasonic Transducer | MA40MF14-1B MA55AF15-07NA MA48AF15-07N | kHz | 100V | the lower the better | muRata series |
| D1 | Reverse Polarity Protection | BAS321 | - | 50 V | _ | |

^{1.} Some of RF1, RF2 and CF1 components may be omitted. Use them according to required EMC robustness.

Table 2. PIN FUNCTION DESCRIPTION

| Pin No. | Pin Name | Туре | Description |
|---------|----------------|--------------|--|
| 1 | RXN (Note 2) | Input | Analog Receiver Negative Input |
| 2 | RXP | Input | Analog Receiver Positive Input |
| 3 | GNDA | Ground | Analog Ground |
| 4 | n.c. | n.c. | Pin not connected |
| 5 | GND | Ground | TX Ground, Digital Ground |
| 6 | DRVA | Output | Driver Output A |
| 7 | DRVC | Output | Driver Output C (Center of winding) |
| 8 | DRVB | Output | Driver Output B |
| 9 | VSUP | Power Supply | Main Power Supply |
| 10 | IO | Input/Output | I/O Line Bidirectional Interface to Master ECU |
| 11 | GNDIO | Ground | I/O Line Ground |
| 12 | TST3 | Input/Output | Test pin 3/Custom Diagnostic Interface |
| 13 | TST2 | Input/Output | Test pin 2/Custom Diagnostic Interface |
| 14 | TST1 | Input/Output | Test pin 1/Custom Diagnostic Interface |
| 15 | TST0 | Input/Output | Test pin 0/Custom Diagnostic Interface |
| 16 | TSTEN (Note 3) | Input | Manufacturer Test Mode Enable |

Both receiver inputs are equal. Anyone of them can be used for signal input and the other for ground reference. But, using outer package pin for signal input may result in worse EMC robustness.

3. TSTEN pin has to be always grounded in customer application. There is no customer functionality.

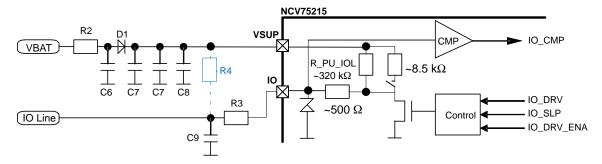


Figure 2. I/O Line Driver Structure and External Network

Table 3. ABSOLUTE MAXIMUM RATINGS

| Rating | Symbol | Value | Units |
|--|---------------------------------------|--|-------|
| Supply Voltage Range VSUP (Note 4) | V _{SUP} | -0.3 to 40 | V |
| I/O Line Voltage Range | V _{IO} | -5 to 40 | V |
| I/O Line Voltage Range (T _A = 25°C) | V _{IO,A} | -15 to 40 | V |
| I/O Line Voltage Range (t _{PULSE} < 1 second, T _A = 25°C) | V _{IO,PA} | -30 to 40 | V |
| Transmitter DRVA, DRVB voltage | V _{DRV} | -0.3 to $(2 \times V_{SUP} + 0.3)$ or 40 | V |
| Transmitter DRVC voltage | V _{DRV} | -0.3 to (V _{SUP} + 0.3) or 40 | V |
| Receiver Input P, N Voltage | V _{RXP} , V _{RXN} | -0.3 to 0.3 | V |
| Testmode Pin Voltage | V _{TST0} – V _{TST3} | 0 to (V _{DD} + 0.3) or 3.6 | V |
| Maximum Junction Temperature | T _{J(max)} | 125 | °C |
| Storage Temperature Range | TSTG | -40 to 125 | °C |
| ESD Capability, Human Body Model (Note 5) | ESDHBM | 2 | kV |
| ESD Capability, Charge Device Model, All Pins (Note 5) | ESDCDM-O | 500 | V |
| ESD Capability, Charge Device Model, Corner Pins (Note 5) | ESDCDM-E | 750 | V |
| Latch-up Immunity at 25°C (Note 5) | LU25C | 200 | mA |
| Latch-up Immunity at 125°C (Note 5) | LU125C | 100 | mA |
| Lead Temperature Soldering Reflow (SMD Styles Only), Pb-Free Versions (Note6) | T _{SLD} | 260 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

ESD Human Body Model tested per AEC-Q100-002 (EIA/JESD22-A114)

ESD Machine Model tested per AEC-Q100-003 (EIA/JESD22-A115)

Latch-up Current Maximum Rating: per JEDEC standard JESD78

Table 4. THERMAL CHARACTERISTICS

| Rating | Symbol | Value | Units |
|--|---------------|-------|-------|
| Thermal Characteristics, TSSOP16 (Note 7) Thermal Resistance, Junction-to-Air (Note 8) | $R_{	hetaJA}$ | 135 | °C/W |

^{7.} Refer to ELECTRICAL CHARACTERISTICS, RECOMMENDED OPERATING RANGES and/or APPLICATION INFORMATION for Safe Operating parameters.

Table 5. RECOMMENDED OPERATING RANGES

| Symbol | Description | Min | Тур | Max | Units |
|----------------|---------------------------------|-----|-----|------------------|-------|
| VSUP | DC Supply Voltage | 6 | 12 | 18 | V |
| VIO | I/O Line Voltage | 0 | | VSUP (Note 9) | V |
| T _A | Ambient Temperature under Bias | -40 | | 85 | °C |
| TJ | Junction Temperature under Bias | -40 | | 125 | °C |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

Refer to ELECTRICAL CHĂRACTERISTICS, RECOMMENDED OPERATING RANGES and/or APPLICATION INFORMATION for Safe Operating parameters.

^{5.} This device series incorporates ESD protection and is tested by the following methods:

^{6.} For information, please refer to our Soldering and Mounting Techniques Reference Manual, SOLDERRM/D

^{8.} Values based on copper area of 645 mm² (or 1 in²) of 1 oz. copper thickness and FR4 PCB substrate.

^{9.} VSUP minimum voltage level might decrease the transmit burst ultrasonic power, it is external circuitry dependent. Transducer equivalent serial resistance is transformed on DRVA,B,C ASSP inputs and might be too high to satisfy both minimum VSUP and maximum TX current. In such a case, transmit driving current proportionally declines.

Table 6. ELECTRICAL CHARACTERISTICS

(VSUP = 6 V to 18 V, TA = -40° C to 85°C, external devices as in application circuit of Figure 1.)

| Symbol | Description | Min | Тур | Max | Units |
|---|--|--|------------|-----------------------------------|--|
| I _{VSUP} | Total VSUP Current Consumption (Normal Mode, No Transmission) | | | 8 | mA |
| I _{VSUP, LOW_PWR} | Total VSUP Current Consumption (Low Power Mode) | | | 1 | mA |
| t _{WAKE} | Wake-up Time from Low Power Mode to Normal Mode | | | 1 | ms |
| RECEIVER AMP | LIFIER | | | | |
| RX_{R_IN} | Receiver Input Resistance | | 87 | | kΩ |
| $RX_{C_{-IN}}$ | Receiver Input Capacitance | | 100 | | pF |
| RX_{GAIN} | Programmable Receiver Gain | 50 | | 110 | dB |
| RX _{GSTEP} | Receiver Gain Step | | 0.5 | | dB |
| RX _{NSTEP} | Receiver Number of Gain Steps | | 127 | | |
| RX _{SENS} | Receiver Sensitivity at Maximum Gain | 12 | | | μV_{PP} |
| RX _{BW} | Receiver Bandwidth | 35 | | 90 | kHz |
| TRANSDUCER D | PRIVER | | | | |
| TX _{CURR} | Programmable Transmitter Current | 50 | | 350 | mA |
| TX _{CSTEP} | Transmitter Current Step | | 4.76 | | mA |
| TX _{NSTEP} | Transmitter Number of Current Steps | | 63 | | |
| TX _{SPREC} | Transmitter Current Tolerance | -20 | | 20 | % |
| | GE AND ITS MONITORING | II. | | | |
| VDD | Internal VDD Supply Voltage | 3.15 | 3.3 | 3.5 | V |
| VDD _{POR} | VDD Level for Power-on-Reset | 2.7 | | 3.1 | V |
| VSUP _{UV} | VSUP Level for Power-on-Reset Release at Start-up, Under-voltage Threshold | 5.1 | | 5.7 | V |
| VSUP _{OV} | VSUP Level for TX Driver Disable (to Protect Drivers), Over-voltage Threshold | 18 | | 20 | V |
| INTERNAL OSCI | LLATOR | | | | I. |
| Fosc | Internal Oscillator Frequency | 9.7 | 10 | 10.3 | MHz |
| I/O LINE INTERF | ACE | II. | | | |
| IO _{ILV} | Threshold Voltage for Digital Low | 0.3 | 0.33 | 0.36 | VSUP |
| IO _{IHV} | Threshold Voltage for Digital High | 0.62 | 0.66 | 0.7 | VSUP |
| IO _{OLV} | Output Voltage Low at I/O Pin (I _{OUT} = 1 mA, Internal Pull-up Activated, R4 Not Used) | 0.4 | 0.65 | 1 | V |
| IO _{SR, STD} | Output Slew Rate (Standard I/O Line Slope) | 0.2 | 0.5 | 0.8 | V/μs |
| IO _{SR, FAST} | Output Slew Rate (Fast I/O Line Slope) | 1 | 1.7 | 2.5 | V/μs |
| 011,17101 | | | | 50 | mA |
| IO _{SCC} | I/O Short Circuit Current | 10 | | 30 | 1111/ |
| IO _{SCC} | | | 320 | | |
| IO _{PU} | Fixed Internal Pull-up Resistor (R_PU_IOL) | 10 200 6 | 320 8.5 | 450 11 | kΩ |
| IO _{PU} IO _{PU, SEL} | Fixed Internal Pull-up Resistor (R_PU_IOL) Selectable Internal Pull-up Resistor | 200 | | 450 | |
| IO _{PU} IO _{PU, SEL} TEMPERATURE | Fixed Internal Pull-up Resistor (R_PU_IOL) Selectable Internal Pull-up Resistor MEASUREMENT AND SHUTDOWN | 200 | | 450 11 | kΩ kΩ |
| $\begin{aligned} & IO_{PU} \\ & IO_{PU,SEL} \\ & \textbf{TEMPERATURE} \\ & T_{MR} \end{aligned}$ | Fixed Internal Pull-up Resistor (R_PU_IOL) Selectable Internal Pull-up Resistor MEASUREMENT AND SHUTDOWN Temperature Measurement Range | 200 | 8.5 | 450 | kΩ |
| IO_{PU} $IO_{PU, SEL}$ $TEMPERATURE$ T_{MR} T_{MRES} | Fixed Internal Pull-up Resistor (R_PU_IOL) Selectable Internal Pull-up Resistor MEASUREMENT AND SHUTDOWN Temperature Measurement Range Temperature Measurement Resolution | 200 6 -60 | | 450 11 150 | kΩ kΩ °C °C |
| IO _{PU} IO _{PU, SEL} TEMPERATURE T _{MR} T _{MRES} T _{A41} | Fixed Internal Pull-up Resistor (R_PU_IOL) Selectable Internal Pull-up Resistor MEASUREMENT AND SHUTDOWN Temperature Measurement Range Temperature Measurement Resolution Temperature Measurement Accuracy at T _J = 42°C | 200 | 8.5 | 450 11 | kΩ kΩ °C |
| IO _{PU} IO _{PU, SEL} TEMPERATURE T _{MR} T _{MRES} T _{A41} T _{A125} | Fixed Internal Pull-up Resistor (R_PU_IOL) Selectable Internal Pull-up Resistor MEASUREMENT AND SHUTDOWN Temperature Measurement Range Temperature Measurement Resolution Temperature Measurement Accuracy at T _J = 42°C Temperature Measurement Accuracy at T _J = 125°C | 200 6 -60 -7 -10 | 8.5 | 450 11 150 7 10 | kΩ kΩ °C °C °C |
| IO _{PU} IO _{PU, SEL} TEMPERATURE T _{MR} T _{MRES} T _{A41} T _{A125} T _{A40} | Fixed Internal Pull-up Resistor (R_PU_IOL) Selectable Internal Pull-up Resistor MEASUREMENT AND SHUTDOWN Temperature Measurement Range Temperature Measurement Resolution Temperature Measurement Accuracy at T _J = 42°C Temperature Measurement Accuracy at T _J = 125°C Temperature Measurement Accuracy at T _J = -40°C | 200 6 -60 -7 -10 -10 | 8.5 | 450 11 150 7 10 10 | kΩ kΩ °C °C °C °C °C |
| IO _{PU} IO _{PU, SEL} TEMPERATURE T _{MR} T _{MRES} T _{A41} T _{A125} T _{A40-} T _{SD} | Fixed Internal Pull-up Resistor (R_PU_IOL) Selectable Internal Pull-up Resistor MEASUREMENT AND SHUTDOWN Temperature Measurement Range Temperature Measurement Resolution Temperature Measurement Accuracy at T _J = 42°C Temperature Measurement Accuracy at T _J = 125°C | 200 6 -60 -7 -10 | 8.5 | 450 11 150 7 10 | kΩ kΩ °C °C °C °C |
| IO_{PU} $IO_{PU, SEL}$ $TEMPERATURE$ T_{MR} T_{MRES} T_{A41} T_{A125} T_{A40-} T_{SD} $EEPROM$ | Fixed Internal Pull-up Resistor (R_PU_IOL) Selectable Internal Pull-up Resistor MEASUREMENT AND SHUTDOWN Temperature Measurement Range Temperature Measurement Resolution Temperature Measurement Accuracy at T _J = 42°C Temperature Measurement Accuracy at T _J = 125°C Temperature Measurement Accuracy at T _J = -40°C Thermal Shutdown | 200 6 -60 -7 -10 -10 140 | 8.5 | 450 11 150 7 10 10 | kΩ kΩ °C °C °C °C °C °C |
| IO _{PU} IO _{PU, SEL} TEMPERATURE T _{MR} T _{MRES} T _{A41} T _{A125} T _{A40-} T _{SD} | Fixed Internal Pull-up Resistor (R_PU_IOL) Selectable Internal Pull-up Resistor MEASUREMENT AND SHUTDOWN Temperature Measurement Range Temperature Measurement Resolution Temperature Measurement Accuracy at T _J = 42°C Temperature Measurement Accuracy at T _J = 125°C Temperature Measurement Accuracy at T _J = -40°C | 200 6 -60 -7 -10 -10 | 8.5 | 450 11 150 7 10 10 | kΩ kΩ °C °C °C °C °C |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

DIGITAL FUNCTIONALITY DESCRIPTION

The digital circuitry consists of the following blocks:

- RST_GEN based on POR (power-on reset) signals, generates internal reset of digital blocks
- CLK_GEN generates CLK_IO_LINE and CLK_EEPROM from internal oscillator
- CFG_MEM configuration parameters storage for the chip functionality (EEPROM shadow RAM)
- EEPROM_CTRL EEPROM controller for accessing EEPROM memory
- I/O_LINE_CTRL protocol and application layer for communication with I/O Line master (ECU) via I/O Line
- DSP_TOP ultrasonic receiver and transmitter control, digital signal processing for ultrasonic receiver

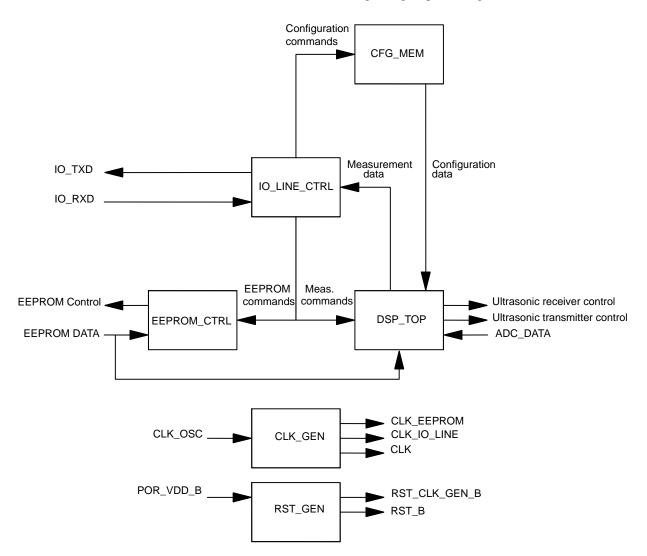


Figure 3. Digital Block Diagram

RST_GEN (Reset Generator)

It generates internal reset signals according to VSUP and VDD levels. In case of thermal shutdown all major blocks, such as RX, TX, and IO_LINE, go to power-down mode. This means that the chip doesn't communicate via I/O Line and its functionality is blocked. Functionality is restored when temperature falls back to a safe level.

CLK_GEN (Clock Generator)

This block generates the timing and internal clock signals based on an on-chip clock oscillator nominally running at 10 MHz (100 ns period).

DSP_TOP (Digital Signal Processing)

This block contains the core of the digital functionality of the NCV75215. The signal from ultrasonic transducer is amplified, converted to digital and fed to DSP_TOP. Then, it is digitally processed and compared to a time-dependent threshold. The echo is reported on I/O Line when the signal magnitude exceeds the threshold. Distance to the obstacle can be determined from the time of the echo arrival. This block also controls transmission and reception at the ultrasonic transducer frequency. A simplified internal diagram of DSP_TOP module is depicted in Figure 4.

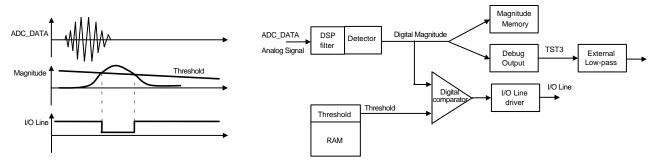


Figure 4. Block Diagram of DST TOP Module (Simplified)

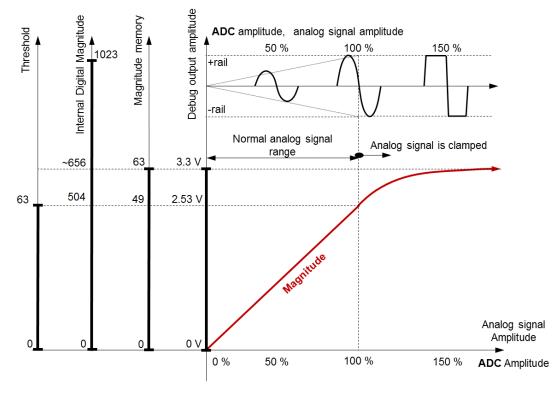


Figure 5. Understanding Internal Digital Magnitude, Thresholds and Debug Amplitude (the Processing is Fully Digital; Voltages Apply to PDM Debugging Outputs TST2 and TST3)

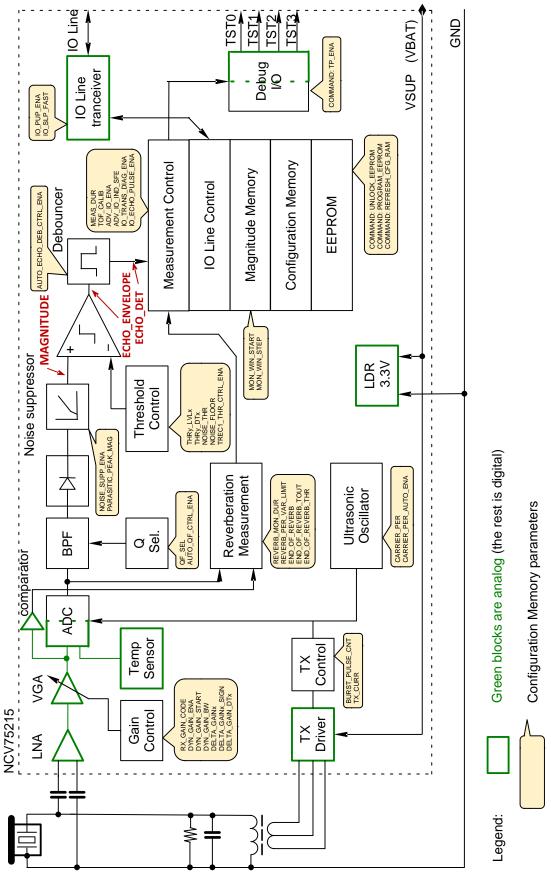


Figure 6. Block Diagram from Signal Processing Point of View

CFG_MEM (Configuration Memory)

Bit structure of configuration memory is described in Table 7. EEPROM Refresh is executed during reset and reset values of CFG_MEM cells are preloaded from EEPROM

when available. For CFG_MEM locations not associated to the EEPROM, default value is preloaded after reset.

Data is transferred over I/O Line LSBit first and lowest sub-index first (in case of data arrays).

Table 7. STRUCTURE OF CONFIGURATION MEMORY

| Conf. Memory | | | No of | | EEPROM | | |
|---|---|---|----------|--|-----------|----------------------------------|-----------|
| index | Name | Short Name | bits | Description | (Note 11) | Default | R/W |
| 0 | Measured Junction Temperature | TEMP [7:0] | 8 | Junction temperature code | | Actual value | R only |
| 1 | Sensor Status (sub-index 0) | SENSOR_STATUS [7:0] | 8 | Refer to Encoding of Sensor Status Section | | Actual value | R only |
| | Measured Reverberation Period (sub-index 1) | MEASURED_ REVERB_PER [10:0] | 11 | 1–LSB ~ 25 ns | | 0 (Note 12) | R only |
| 2a Accessible only when TX_RX_PER_ENA = 0 | Carrier TX / RX Period | CARRIER_PER [10:0] | 11 | 1-LSB ~ 25 ns Transmission & Reverberation: TX_CARRIER_PER = CARRIER_PER + 2 × DTX_PER Reception: RX_CARRIER_PER = CARRIER_PER + 2 × DRX_PER Valid range: <30 kHz, 95 kHz> | Yes | | R/W |
| 2b Accessible only when TX_RX_PER_ENA = 1 | Delta TX Period (sub-index 0) | DTX_PER [7:0] | 8 | 1–LSB ~ 50 ns Two's complement signed number Range: <–6.4 μs, 6.35 μs> See CARRIER_PER for explanation | | 0 | R/W |
| Acce TX_F | Delta Rx Period (sub-index 1) | DRX_PER [7:0] | 8 | The same coding as DTX_PER See CARRIER_PER for explanation | | 0 | R/W |
| 3 | TX Burst Pulse Count | BURST_PULSE_ CNT [4:0] | 5 | Number of TX pulses (031) 0: TX driver is not activated 1: 1 × TX pulse 31: 31 × TX pulses | | 16 | R/W |
| 4 | Measurement Duration | MEAS_DUR [3:0] | 4 | $\begin{array}{c} 0-T_{SNDx} \text{ and } T_{RECx} \text{ I/O Line} \\ \text{commands disabled (default)} \\ 1-6 \text{ ms, } 2-12 \text{ ms} \\ 3-18 \text{ ms, } 4-24 \text{ ms} \\ 5-30 \text{ ms, } 6-36 \text{ ms} \\ 7-42 \text{ ms, } 8-48 \text{ ms} \\ 9-54 \text{ ms, } 10-60 \text{ ms} \\ \text{other values}-60 \text{ ms} \end{array}$ | | 0 | R/W |
| 5 | THR1 | THR1_LVL0 [5:0] / DT0 [3:0] THR1_LVL11 / DT11 | 120 | Thresholds – THR1 table See section THRESHOLDS | | THR1_ LVLx = 32 DTx = 0 | R/W |
| 6 | THR2 | THR2_LVL0 [5:0] / DT0 [3:0] THR2_LVL11 / DT11 | 120 | Thresholds – THR2 table See section THRESHOLDS | | THR2_ LVLx = 32 DTx = 0 | R/W |

Table 7. STRUCTURE OF CONFIGURATION MEMORY (continued)

| Conf. Memory | | | No of | | EEPROM | | |
|-----------------|--|-------------------------|----------|---|-----------|---------|-----|
| index | Name | Short Name | bits | Description | (Note 11) | Default | R/W |
| 7 | Static RX Gain Code (sub-index 0) | RX_GAIN_CODE [6:0] | 7 | RX Gain Code 1-LSB ~ 0.476 dB | Yes | | R/W |
| | Dynamic Gain Control Enable (sub-index 1) | DYN_GAIN_ENA | 1 | Enables / disables dynamic gain | Yes | | R/W |
| | Noise Threshold (sub-index 2) | NOISE_THR [5:0] | 6 | Threshold applied during noise monitoring | | 32 | R/W |
| | Noise Floor (sub-index 3) | NOISE_FLOOR [5:0] | 6 | All thresholds below NOISE_FLOOR[5:0] are clamped to NOISE_FLOOR[5:0]. Signal be- low NOISE_FLOOR[5:0] is con- sidered as noise. The same coding as thresh- olds. | | 4 | R/W |
| 8 | Dynamic Gain – Delta Gain #0 (sub-index 0) | DELTA_GAIN0 [6:0] | 7 | See DYNAMIC GAIN section. Range 0127 | | 0 | R/W |
| | Dynamic Gain – Delta Gain Sign #0 (sub-index 1) | DELTA_GAIN0_SIGN | 1 | See DYNAMIC GAIN section. 0positive, 1negative | | 0 | R/W |
| | Dynamic Gain – Delta Gain #1 (sub-index 2) | DELTA_GAIN1 [6:0] | 7 | See DYNAMIC GAIN section. Range 0127 | | 0 | R/W |
| | Dynamic Gain – Delta Gain Sign #1 (sub-index 3) | DELTA_GAIN1_SIGN | 1 | See DYNAMIC GAIN section. 0positive, 1negative | | 0 | R/W |
| | Dynamic Gain – Delta Gain #2 (sub-index 4) | DELTA_GAIN2 [6:0] | 7 | See DYNAMIC GAIN section. Range 0127 | | 0 | R/W |
| | Dynamic Gain – Delta Gain Sign #2 (sub-index 5) | DELTA_GAIN2_SIGN | 1 | See DYNAMIC GAIN section. 0positive, 1negative | | 0 | R/W |
| | Dynamic Gain – Delta Gain #3 (sub-index 6) | DELTA_GAIN3 [6:0] | 7 | See DYNAMIC GAIN section. Range 0127 | | 0 | R/W |
| | Dynamic Gain – Delta Gain Sign #3 (sub-index 7) | DELTA_GAIN3_SIGN | 1 | See DYNAMIC GAIN section. 0positive, 1negative | | 0 | R/W |
| | Dynamic Gain – Delta Gain #4 (sub-index 8) | DELTA_GAIN4 [6:0] | 7 | See DYNAMIC GAIN section. Range 0127 | | 0 | R/W |
| | Dynamic Gain – Delta Gain Sign #4 (sub-index 9) | DELTA_GAIN4_SIGN | 1 | See DYNAMIC GAIN section. 0positive, 1negative | | 0 | R/W |
| | Dynamic Gain – Delta Time Code #0 (sub-index 10) | DELTA_GAIN_DT0 [3:0] | 4 | See DYNAMIC GAIN section. | | 0 | R/W |
| | Dynamic Gain – Delta Time Code #1 (sub-index 11) | DELTA_GAIN_DT1 [3:0] | 4 | See DYNAMIC GAIN section. | | 0 | R/W |
| | Dynamic Gain – Delta Time Code #2 (sub-index 12) | DELTA_GAIN_DT2 [3:0] | 4 | See DYNAMIC GAIN section. | | 0 | R/W |
| | Dynamic Gain – Delta Time Code #3 (sub-index 13) | DELTA_GAIN_DT3 [3:0] | 4 | See DYNAMIC GAIN section. | | 0 | R/W |
| | Dynamic Gain – Delta Time Code #4 (sub-index 14) | DELTA_GAIN_DT4 [3:0] | 4 | See DYNAMIC GAIN section. | | 0 | R/W |

Table 7. STRUCTURE OF CONFIGURATION MEMORY (continued)

| Conf. Memory | | | No of | | EEPROM | | |
|-----------------|---|--------------------------------|----------|---|-----------|---------|-----|
| index | Name | Short Name | bits | Description | (Note 11) | Default | R/W |
| 8 | Dynamic Gain Control Start (sub-index 15) | DYN_GAIN_START [3:0] | 4 | DYN_GAIN_START × 204.8 μs | | 0 | R/W |
| | Dynamic Gain – Filter BW (sub-index 16) | DYN_GAIN_BW [1:0] | 2 | See DYNAMIC GAIN section. | | 0 | R/W |
| 9 | Generic User Data | USER_DATA [119:0] | 120 | 120 bits of user data. User can select any structure. The chip doesn't internally use this data. | Yes | | R/W |
| 10 | Reverberation / Decay Monitoring Window Duration (sub-index 0) | REVERB_MON_DUR [7:0] | 8 | 1–LSB ~ 25.6 μs | Yes | | R/W |
| | Current Adjustment (sub-index 1) | TX_CURR [5:0] | 6 | Default value is pre-loaded after POR. | Yes | | R/W |
| | Reverberation Period Variation Limit (sub-index 2) | REVERB_PER_ VAR_LIMIT [1:0] | 2 | 0 – 2.34 % 1 – 5.4 % 2 – 8.2 % 3 – 12.5 % | Yes | | R/W |
| | Monitoring Window Start (sub-index 3) | MON_WIN_START [11:0] | 12 | Start time of echo magnitude logging into measurement memory 1–LSB ~ 25.6 µs | | 0 | R/W |
| | Monitoring Window Step (sub-index 4) | MON_WIN_STEP [1:0] | 2 | Magnitude sampling period 0: 25.6 μs 1: 51.2 μs 2: 102.4 μs 3: 204.8 μs | | 1 | R/W |
| | Automatic Carrier Period Control (sub-index 5) | CARRIER_PER_ AUTO_ENA | 1 | When 1: CARRIER_PER is used as carrier period for 1st ultrasonic measurement only resp. each time CARRIER_PER is updated. Following measurements will drive TX with measured MEASURED_REVERB_PER auto- | Yes | | R/W |
| | | | | matically only if difference be- tween CARRIER_PER and measured reverberation period is less than RE- VERB_PER_VAR_LIMIT other- wise CARRIER_PER is used. | | | |
| | | | | In case of indirect measure- ment the CARRIER_PER will be exclusively used for echo re- ception. | | | |
| | | | | When 0: TX_CARRIER_PER resp. RX_CARRIER_PER is used. | | | |
| | Noise Suppression Enable (sub-index 6) | NOISE_SUPP_ENA | 1 | Echo magnitude is suppressed if it is below noise background level | Yes | | R/W |
| 10 | ToF Calibration (sub-index 7) | TOF_CALIB [5:0] | 6 | The time is subtracted from measured ToF prior storing it into the measurement result registers. | Yes | | R/W |
| | | | | It needs to be adjusted for selected Q factor. 1–LSB ~ 25.6 μs | | | |

Table 7. STRUCTURE OF CONFIGURATION MEMORY (continued)

| Conf. Memory | | | No of | | EEPROM | | |
|-----------------|---|----------------------------|----------|--|-----------|---------|-----|
| index | Name | Short Name | bits | Description | (Note 11) | Default | R/W |
| | Reverberation Debounce Time (sub-index 8) | END_OF_REVERB [1:0] | 2 | Debounce time is improving robustness towards chattering phenomena 0: 60 μs 1: 100 μs 2: 140 μs 3: 180 μs | | 1 | R/W |
| | DSP Filter Q Factor Selection (sub-index 9) | QF_SEL [1:0] | 2 | 0: Q = 5 1: Q = 10 2: Q = 20 3: Q = depending on number of TX pulses TX pulses Q 011 5 1223 10 2431 20 | | 1 | R/W |
| | DSP Filter Auto Q Factor Control Enable (sub-index 10) | AUTO_QF_CTRL_ ENA | 1 | O: Fixed Q factor according to QF_SEL [1:0] 1: Q is automatically switched at 14.8 ms after start of measurement | | 0 | R/W |
| | | | | QF_SEL Q start Q after 14.8 ms 0 5 10 1 5 20 2 10 20 3 5 Depends on TX pulses | | | |
| | Automatic Echo Debounce Time Control Enable (sub-index 11) | AUTO_ECHO_DEB_ CTRL_ENA | 1 | 0: Fixed 60 μs 1: Fixed 60 μs is automatically switched to 200 μs at 14.8 ms after start of measurement | | 0 | R/W |
| | Internal I/O Line Pull-up Enable (sub-index 12) | IO_PUP_ENA | 1 | O: Internal I/O Line pull-up disabled I: Internal I/O Line pull-up enabled | Yes | | R/W |
| | I/O Line Slope Control (sub-index 13) | IO_SLP_FAST | 1 | 0: Standard I/O Line slope (60 μs) 1: Fast I/O Line slope (20 μs) | Yes | | R/W |
| | Advance I/O Line Protocol Enable (sub-index 14) | ADV_IO_ENA | 1 | O: Standard I/O Line protocols Advanced I/O Line protocol Please, see index 13 & 14 for more details. | | 0 | R/W |
| | T _{REC1} Threshold Control Enable (sub-index 15) | TREC1_THR_CTRL_ ENA | 1 | 0: T _{REC1} utilizes THR1 curve 1: T _{REC1} utilizes fixed threshold NOISE_THR and fixed static gain RX_GAIN_CODE. SENSOR_STATUS [0] (Acoustic Noise Flag) is ORed with SENSOR_STATUS[0] of following T _{SND1} /T _{SND2} resp. T _{REC2} . | | 0 | R/W |

Table 7. STRUCTURE OF CONFIGURATION MEMORY (continued)

| Conf. Memory | | | No of | | EEPROM | | |
|-----------------|--|------------------------------|----------|---|-----------|---------------|-----|
| index | Name | Short Name | bits | Description | (Note 11) | Default | R/W |
| 10 | End of Reverberation Time-out (sub-index 16) | END_OF_REVERB_ TOUT [5:0] | 6 | Time-out of end-of-reverberation. In presence of high noise, the signal magnitude at analog front-end may avoid proper detection of end-of-reverberation. Detection of end-of-reverberation is mandatory prior to start of echo detection. This function stops end-of-reverberation measurement by time-out. Improper use may lead to fake echo detection (reverberation detected as echo). 1–LSB ~ 51.2 μs It is measured from TX end, end-of-reverberation time-out = TX end + END_OF_RE-VERB_TOUT[5:0]×51.2 μs SENSOR_STATUS[5] is set in case the reverberation time-out is detected. | | 39 (~2 ms) | R/W |
| | Advanced I/O Line Indirect Measurement Skip First Echo (sub-index 17) | ADV_IO_IND_SFE | 1 | O: ToF1 = 1st echo; ToF2 = 2nd echo 1: ToF1 = 2nd echo; ToF2 = 3rd echo (valid for advanced I/O Line indirect measurement mode only) Comment: In case of indirect measurement, 1st echo is echo from sensor performing direct measurement. This option is valid for indirect measurement only. | | 1 | R/W |
| | I/O Line Transducer Diagnostic Reporting Enable (sub-index 18) | IO_TRANS_DIAG_ ENA | 1 | O: Reporting of transducer diagnostic at I/O Line disabled 1: Reporting of transducer diagnostic at I/O Line enabled Comment: Transducer diagnostic is always enabled when Advanced I/O Line protocol is enabled (ADV_IO_ENA = 1) | | 1 | R/W |
| | End of Reverberation Threshold (sub-index 19) | END_OF_REVERB_ THR | 1 | 0: 75% of full-scale 1: 50% of full-scale | | 0 | R/W |

Table 7. STRUCTURE OF CONFIGURATION MEMORY (continued)

| Conf. Memory | | VI IGUNATION MILMOI | No of | , | EEPROM | | |
|-----------------|---|------------------------------|----------|--|-----------|---------|-----|
| index | Name | Short Name | bits | Description | (Note 11) | Default | R/W |
| 10 | I/O Line 99.2 μs Echo Duration Enabled (sub-index 20) | IO_ECHO_PULSE_ ENA | 1 | O: Disabled 1: Enabled, valid only when ADV_IO_ENA = 0. When enabled, echo is always reported by 99.2 μs pulse on I/O Line. Measurement is stopped If I/O Line is pulled low for at least 350 μs during active measure- | | 0 | R/W |
| | | | | ment. Once active measurement is stopped, I/O Line has to be released to idle state (high) for at least T _{DEB} time to re-enable the detection of next I/O Line command. | | | |
| | | | | In case of T_{SNDx} , I/O Line is driven low for 99.2 μ s at the detected end of reverberations, then I/O Line is again driven low for 99.2 μ s each time when valid echo is detected (this is identical with T_{RECx}). Min. time is 99.2 μ s between | | | |
| | | | | two echoes in this mode. If distance between echoes is less than 99.2 μs just single echo is reported. Comment: This mode enables | | | |
| | | | | fully programmable measure- ment duration (by stopping of on-going measurement) while it is still transparently propagating detected echo (ToF) on I/O Line. | | | |
| | Parasitic Echo Peak Magnitude to Suppress at the End of Reverberations (sub-index 21) | PARASITIC_PEAK_ MAG [1:0] | 2 | Parasitic echo peak suppression is disabled at the end of reverberations Parasitic echo peak low suppression Parasitic echo peak medium suppression Parasitic echo peak high suppression | | 0 | R/W |
| | Index 2 Format Selection (sub-index 22) | TX_RX_PER_ENA | 1 | Selects format 2a Selects format 2b | | 0 | R/W |
| | Index 14 Format Selection (sub-index 23) | WIDTH_PEAK_ENA | 1 | 0: Selects format 14a 1: Selects format 14b | | 0 | R/W |
| 11 | Super Read/Write Index | n.a. (Note 10) | | READ: Sequential read of the following indexes in the following order: 2a, 7. RX_GAIN_CODE, 7. DYN_GAIN_ENA, 10 (items initialized from EEPROM only) | | n.a. | R/W |
| | | | | WRITE: Sequential write to the following indexes in the following order: 2a, 3, 4, 7, 10 | | | |

Table 7. STRUCTURE OF CONFIGURATION MEMORY (continued)

| Conf. Memory | | | No of | | EEPROM | | |
|---|---|--|----------|--|-----------|---------|-----------|
| index | Name | Short Name | bits | Description | (Note 11) | Default | R/W |
| 12 | Magnitude Data | MEAS_DATA0 [5:0] MEAS_DATA59 [5:0] | 360 | Sampled echo magnitude. Echo magnitude logging is controlled by parameters MON_WIN_START and MON_WIN_STEP. MEAS_DATA0 = echo magnitude at time MON_WIN_START × 25.6 μs MEAS_DATA59 = echo magnitude at time MON_WIN_START × 25.6 μs + 59 × LUT[MON_WIN_STEP] | | n.a. | R |
| 13 | Measurement Results – Short This index is only | MEAS_RES_SHR_ SENSOR_STATUS [7:0] (sub-index 0) | 8 | Refer to Encoding of Sensor Status Section | | n.a. | R only |
| | functional when ADV_IO_ENA = 1. Otherwise, there is no response for this index. | MEAS_RES_SHR_ TOF1 [9:0] (sub-index 1) | 10 | ToF1 – time of 1st echo 1–LSB ~ 51.2 μ s ToF = floor (echo detection time) – (TOF_CALIB × 25.6 μ s) Echo time – 1st (ToF1) rising edge of ECHO_DET signal after detected end of reverberation ToF1 = 0 in case the echo is not detected | | 0 | R only |
| | Measurement Results – Long This index is only functional when | MEAS_RES_LNG_ SENSOR_STATUS [7:0] (sub-index 0) | 8 | Refer to Encoding of Sensor Status Section | | n.a | R only |
| 14a Accessible only when WIDTH_PEAK_ENA = 0 | ADV_IO_ENA = 1. Otherwise, there is no response for this index. | MEAS_RES_LNG_ TOF1 [9:0] (sub-index 1) | 10 | ToF1 – time of 1 st echo 1–LSB ~ 51.2 μs See index 13. ToFx = 0 in case when any echo is not detected | | 0 | R only |
| > | | MEAS_RES_LNG_ TOF2 [9:0] (sub-index 2) | 10 | ToF2 – time of 2 nd echo | | 0 | R only |

Table 7. STRUCTURE OF CONFIGURATION MEMORY (continued)

| Conf. | | | No | | | | |
|---|---|--|------|---|-----------|-------------------|-----------|
| Memory | | | of | | EEPROM | | |
| index | Name | Short Name | bits | Description | (Note 11) | Default | R/W |
| | Measurement Results – Long This index is only | MEAS_RES_LNG_ SENSOR_STATUS [7:0] (sub-index 0) | 8 | Refer to Encoding of Sensor Status Section | | n.a | R only |
| 14b Accessible only when WIDTH_PEAK_ENA = 1 | functional when ADV_IO_ENA = 1. Otherwise, there is no response for this index. | MEAS_RES_LNG_ TOF1 [9:0] (sub-index 1) | 10 | ToF1 – time of 1 st echo 1–LSB ~ 51.2 μs See index 13. ToFx = 0 in case when any echo is not detected | | 0 | R only |
| Ao | | MEAS_RES_LNG_ PEAK1 [5:0] (sub-index 2) | 6 | Maximal magnitude of 1st echo. The same encoding as echo magnitude in MEAS_DATA. In case of no echo, it is 0. | | 0 | R only |
| | | MEAS_RES_LNG_ WIDTH1 [5:0] (sub-index 3) | 6 | Width of 1 st echo. 1–LSB ~ 12.8 μs In case of no echo, it is 0. | | 0 | R only |
| 15 | Command Byte (Write) IC Revision ID (Read) | CMD[7:0] / IC_ID_xx[7:0] | 8 | See Data communication section. WRITE: CMD [7:0] command byte READ: IC_ID_xx [7:4]: Full mask version Allowed range from 1 to15. IC_ID_xx [3:0]: Metal tune version Allowed range from 1 to15. Comment: 1st silicon version is IC_ID_xx = 0x11 hex | | IC_ID_xx [7:0] | R/W |

^{10.} n.a. = not applicable 11. Configuration memory start-up values:

| EEPROM Column Value in Table 1 | Configuration Memory Item Start-up Value | |
|--------------------------------|--|--|
| Yes | The value is preloaded from EEPROM at start-up. | |
| - | Default value is loaded at start-up or actual value is reported (read only items). | |

12.MEASURED_REVERB_PER values:

| MEASURED_REVERB_PER Value | Value Meaning |
|---------------------------|--|
| 0 | The period not measured. |
| 1 | The period measurement failed because of low signal. |
| Others | Measured period. |

ENCODING OF SENSOR_STATUS [7:0] REGISTER

SENSOR_STATUS [0] = Acoustic Noise Flag

Flag is set if an acoustic noise is above the noise threshold (NOISE THR) in noise monitoring time window.

Flag is automatically cleared by any measurement.

SENSOR_STATUS [1] = VSUP Under-voltage or Over-voltage during TX

Flag is set if VSUP voltage is below under-voltage threshold or crosses the over-voltage threshold during TX. If the VSUP voltage is higher than over-voltage threshold before TX, then the flag is not set.

In any case when over-voltage was detected during TX, transmission is automatically stopped, but measurement normally continues.

Flag is automatically cleared by direct measurement only.

SENSOR_STATUS [2] = TX Period Update Required

Flag is set if MEASURED_REVERB_PER is outside the range set by REVERB_PER_VAR_LIMIT and CARRIER_PER. Flag is updated by direct measurement only. Flag is automatically cleared by direct measurement only.

Flag is set after POR.

SENSOR_STATUS [3] = TX Period Update Direction

Flag indicates if MEASURED_REVERB_PER is greater than CARRIER PER.

Flag is updated by direct measurement only. Flag is automatically cleared by direct measurement only.

SENSOR_STATUS [4] = Unexpected Decay Time (decay time too short)

Flag is set if transducer decay time (reverberation) is shorter than REVERB_MON_DUR time.

Flag is updated by direct measurement only. Flag is automatically cleared by direct measurement only.

SENSOR_STATUS [5] = End of Reverberation Time-out

Flag is set if transducer decay time is longer than end-of-reverberation time-out (TX end + END_OF_REVERB_TOUT * 51.2 μ s). Flag is updated by direct measurement only. Flag is automatically cleared by direct measurement only.

SENSOR_STATUS [6] = THS_ERROR Flag (Thermal Shutdown Error)

Flag is set if thermal shutdown is detected. Flag is automatically cleared by any measurement.

SENSOR_STATUS [7] = EEPROM Two-Bit Error or EEPROM CRC Error or POR flag

EEPROM Two-Bit Error Flag:

Flag is updated by refreshing Configuration RAM from EEPROM (at start-up or initialized by Refresh Configuration RAM from EEPROM command). Flag is set if two-bit error is detected at any EEPROM address (single-bit error is automatically corrected by ECC code).

EEPROM CRC Error Flag:

Flag is updated by refreshing Configuration RAM from EEPROM (at start-up or initialized by Refresh Configuration RAM from EEPROM command). EEPROM data (ECC bits not included) CRC code is automatically calculated and stored into EEPROM as a part of Program EEPROM process. CRC stored in EEPROM is compared with CRC calculated during Refresh Configuration RAM from EEPROM process. Flag is set if stored and calculated CRC don't match. CRC is also protected by ECC.

The CRC8–C2 polynomial is $x^8+x^5+x^3+x^2+x+1$. The initial value is "1111_1111" binary.

POR Flag:

The flag is set at POR and it is cleared-by-read.

NOTES: a.) If flags are updated in case of direct (transmit and receive) measurement only, they are kept unchanged in case of indirect (receive only) measurement.

b.) Clear-by-read flags are cleared by reading of Configuration RAM index 1.

CONFIGURATION MEMORY DETAILED DATA STRUCTURES

Table 8. INDEX 0 DATA STRUCTURE (Data are transferred LSBit first.)

| Data Frame Byte | Data Frame Bit | Threshold Table Bit |
|-----------------|----------------|----------------------|
| 0 | 0 | TEMPERATURE_CODE [0] |
| | | |
| | 7 | TEMPERATURE_CODE [7] |

Table 9. INDEX 1 DATA STRUCTURE (Data are transferred LSBit first.)

| Data Frame Byte | Data Frame Bit | Threshold Table Bit |
|-----------------|----------------|--------------------------|
| 0 | 0 | SENSOR_STATUS [0] |
| | | |
| | 7 | SENSOR_STATUS [7] |
| 1 | 8 | MEASURED_REVERB_PER [0] |
| | | |
| | 15 | MEASURED_REVERB_PER [7] |
| 2 | 16 | MEASURED_REVERB_PER [8] |
| | 17 | MEASURED_REVERB_PER [9] |
| | 18 | MEASURED_REVERB_PER [10] |

Table 10. INDEX 2A DATA STRUCTURE (Data are transferred LSBit first.)

| Data Frame Byte | Data Frame Bit | Threshold Table Bit |
|-----------------|----------------|---------------------|
| 0 | 0 | CARRIER_PER [0] |
| | | |
| | 7 | CARRIER_PER [7] |
| 1 | 8 | CARRIER_PER [8] |
| | 9 | CARRIER_PER [9] |
| | 10 | CARRIER_PER [10] |

Table 11. INDEX 2B DATA STRUCTURE (Data are transferred LSBit first.)

| Data Frame Byte | Data Frame Bit | Threshold Table Bit |
|-----------------|----------------|---------------------|
| 0 | 0 | DTX_PER [0] |
| | | |
| | 7 | DTX_PER [7] |
| 1 | 8 | DRX_PER [0] |
| | | |
| | 15 | DRX_PER [7] |

Table 12. INDEX 7 DATA STRUCTURE (Data are transferred LSBit first.)

| Data Frame Byte | Data Frame Bit | Threshold Table Bit |
|-----------------|----------------|---------------------|
| 0 | 0 | RX_GAIN_CODE [0] |
| | | |
| | 6 | RX_GAIN_CODE [6] |
| | 7 | DYN_GAIN_ENA |

Table 12. INDEX 7 DATA STRUCTURE (Data are transferred LSBit first.) (continued)

| Data Frame Byte | Data Frame Bit | Threshold Table Bit |
|-----------------|----------------|---------------------|
| 1 | 8 | NOISE_THR [0] |
| | | |
| | 13 | NOISE_THR [5] |
| | 14 | NOISE_FLOOR [0] |
| | 15 | NOISE_FLOOR [1] |
| 2 | 16 | NOISE_FLOOR [2] |
| | 17 | NOISE_FLOOR [3] |
| | 18 | NOISE_FLOOR [4] |
| | 19 | NOISE_FLOOR [5] |

Table 13. INDEX 10 DATA STRUCTURE (Data are transferred LSBit first.)

| Data Frame Byte | Data Frame Bit | Threshold Table Bit | |
|-----------------|----------------|--------------------------|--|
| 0 | 0 | REVERB_MON_DUR [0] | |
| | | | |
| · | 7 | REVERB_MON_DUR [7] | |
| 1 | 8 | TX_CURR [0] | |
| | | | |
| | 13 | TX_CURR [5] | |
| | 14 | REVERB_PER_VAR_LIMIT [0] | |
| | 15 | REVERB_PER_VAR_LIMIT [1] | |
| 2 | 16 | MON_WIN_START [0] | |
| | | | |
| | 23 | MON_WIN_START [7] | |
| 3 | 24 | MON_WIN_START [8] | |
| · | | | |
| | 27 | MON_WIN_START [11] | |
| · | 28 | MON_WIN_STEP [0] | |
| | 29 | MON_WIN_STEP [1] | |
| · | 30 | CARRIER_PER_AUTO_ENA | |
| · | 31 | NOISE_SUPP_ENA | |
| 4 | 32 | TOF_CALIB [0] | |
| · | | | |
| · | 37 | TOF_CALIB [5] | |
| · | 38 | END_OF_REVERB [0] | |
| · | 39 | END_OF_REVERB [1] | |
| 5 | 40 | QF_SEL [0] | |
| · | 41 | QF_SEL [1] | |
| | 42 | AUTO_QF_CTRL_ENA | |
| | 43 | AUTO_ECHO_DEB_CTRL_ENA | |
| | 44 | IO_PUP_ENA | |
| | 45 | IO_SLP_FAST | |
| | 46 | ADV_IO_ENA | |
| | 47 | TREC1_THR_CTRL_ENA | |

Table 13. INDEX 10 DATA STRUCTURE (Data are transferred LSBit first.) (continued)

| Data Frame Byte | Data Frame Bit | Threshold Table Bit |
|-----------------|----------------|------------------------|
| 6 | 48 | END_OF_REVERB_TOUT [0] |
| | | |
| | 53 | END_OF_REVERB_TOUT [5] |
| | 54 | ADV_IO_IND_SFE |
| | 55 | IO_TRANS_DIAG_ENA |
| 7 | 56 | END_OF_REVERB_THR |
| | 57 | IO_ECHO_PULSE_ENA |
| | 58 | PARASITIC_PEAK_MAG [0] |
| | 59 | PARASITIC_PEAK_MAG [1] |
| | 60 | TX_RX_PER_ENA |
| | 61 | WIDTH_PEAK_ENA |

Table 14. INDEX 12 DATA STRUCTURE (Data are transferred LSBit first.)

| Data Frame Byte | Data Frame Bit | Threshold Table Bit |
|-----------------|----------------|---------------------|
| 0 | 0 | MEAS_DATA0 [0] |
| | | |
| | 5 | MEAS_DATA0 [5] |
| | 6 | MEAS_DATA1 [0] |
| | 7 | MEAS_DATA1 [1] |
| 1 | 8 | MEAS_DATA1 [2] |
| | | |
| | 11 | MEAS_DATA1 [5] |
| | 12 | MEAS_DATA2 [0] |
| | | |
| | 15 | MEAS_DATA2 [3] |
| 2 | 16 | MEAS_DATA2 [4] |
| | 17 | MEAS_DATA2 [5] |
| | 18 | MEAS_DATA3 [0] |
| | | |
| | 23 | MEAS_DATA3 [5] |
| | | |
| 44 | 352 | MEAS_DATA58 [4] |
| ļ | 353 | MEAS_DATA58 [5] |
| ļ | 354 | MEAS_DATA59 [0] |
| † | | |
| † | 359 | MEAS_DATA59 [5] |

NOTES:

- The content of registers MEAS_DATA0..59 is undefined and lost if I/O Line short to VBAT/GND is detected during reading from configuration memory index 12.
- The registers are updated during measurement.

 They can be read as many times as required, but their content is lost when any index data write transfer is issued on I/O Line.

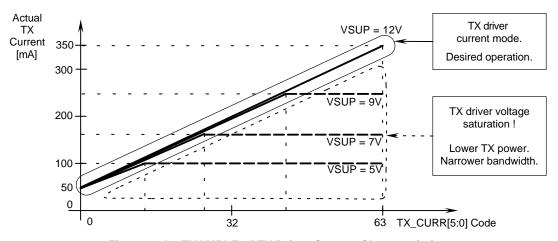


Figure 7. An EXAMPLE of TX Driver Current Characteristics

Figure 7 depicts an EXAMPLE of TX driver current characteristic. The characteristic doesn't depend on

NCV75215 but it depends on utilized transformer and the piezo impedance transformed to primary winding.

Table 15. INDEX 13 DATA STRUCTURE (Data are transferred LSBit first.)

| Data Frame Byte | Data Frame Bit | Threshold Table Bit | |
|-----------------|----------------|-----------------------|--|
| 0 | 0 | SENSOR_STATUS [0] | |
| | | | |
| | 7 | SENSOR_STATUS [7] | |
| 1 | 8 | MEAS_RES_SHR_TOF1 [0] | |
| | | | |
| | 15 | MEAS_RES_SHR_TOF1 [7] | |
| 2 | 16 | MEAS_RES_SHR_TOF1 [8] | |
| | 17 | MEAS_RES_SHR_TOF1 [9] | |

Table 16. INDEX 14A DATA STRUCTURE (Data are transferred LSBit first.)

| Data Frame Byte | Data Frame Bit | Threshold Table Bit | |
|-----------------|----------------|-----------------------|--|
| 0 | 0 | SENSOR_STATUS [0] | |
| | | | |
| | 7 | SENSOR_STATUS [7] | |
| 1 | 8 | MEAS_RES_LNG_TOF1 [0] | |
| | | | |
| | 15 | MEAS_RES_LNG_TOF1 [7] | |
| 2 | 16 | MEAS_RES_LNG_TOF1 [8] | |
| | 17 | MEAS_RES_LNG_TOF1 [9] | |
| | 18 | MEAS_RES_LNG_TOF2 [0] | |
| | | | |
| | 23 | MEAS_RES_LNG_TOF2 [5] | |
| 3 | 24 | MEAS_RES_LNG_TOF2 [6] | |
| | | | |
| | 27 | MEAS_RES_LNG_TOF2 [9] | |

Table 17. INDEX 14B DATA STRUCTURE (Data are transferred LSBit first.)

| Data Frame Byte | Data Frame Bit | Threshold Table Bit |
|-----------------|-------------------|-------------------------|
| 0 | 0 | SENSOR_STATUS [0] |
| | | |
| | 7 | SENSOR_STATUS [7] |
| 1 | 8 | MEAS_RES_LNG_TOF1 [0] |
| | | |
| | 15 | MEAS_RES_LNG_TOF1 [7] |
| 2 | 16 | MEAS_RES_LNG_TOF1 [8] |
| | 17 | MEAS_RES_LNG_TOF1 [9] |
| | 18 | MEAS_RES_LNG_PEAK1 [0] |
| | | |
| | 23 | MEAS_RES_LNG_PEAK1 [5] |
| 3 | 3 24 MEAS_RES_LNC | |
| | | |
| | 29 | MEAS_RES_LNG_WIDTH1 [5] |

TEMPERATURE MEASUREMENT

It is possible to monitor junction temperature by reading configuration memory index 0.

Table 18. JUNCTION TEMPERATURE CONVERSION

| Junction Temperature | TEMP[7:0] – Config. Mem. ldx 0 |
|----------------------|--------------------------------|
| -60 | 16 |
| -40 | 36 |
| -20 | 56 |
| 0 | 76 |
| 20 | 95 |
| 40 | 116 |
| 60 | 136 |
| 80 | 156 |
| 100 | 176 |
| 120 | 197 |
| 140 | 217 |
| 160 | 238 |
| 170 | 248 |

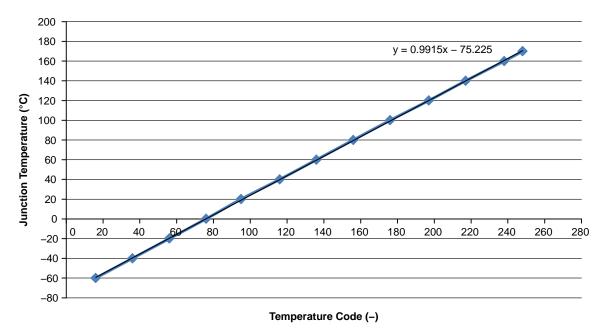


Figure 8. Junction Temperature Transfer Function

THRESHOLDS

DSP Filter Threshold (signal magnitude threshold) is controlled by values in 1 of 2 threshold Look-Up Tables (THR1 or THR2). The last threshold interval ends at 60ms (measured from the beginning of TX Ultrasonic transmission). Each threshold table consists of 12 data pairs. Each pair contains threshold level (6 bit) and delta time code (4 bit), which defines a time for linear interpolation to the particular threshold level. Threshold levels are interpreted using linear scale.

Table 19. THRESHOLD TABLE SELECTION

| Command Pulse (Measurement Type) | Threshold Table Used |
|--|----------------------|
| T _{SND1} or T _{REC1} | THR1 |
| T _{SND2} or T _{REC2} | THR2 |

Table 20. THRESHOLD LEVELS THRx_LVLy[5:0] (Note 13)

| Value | Interpretation |
|--------|---------------------------------------|
| 0 | Lowest threshold level |
| | |
| 63 | Highest threshold level |
| (0x3F) | (equivalent of full ADC range signal) |

Table 21. THRESHOLD DELTA TIME THRx_DTy[3:0] (Note 13)

| THRx_DTy Code | Delta Time [μs] | THRx_DTy Code | Delta Time [μs] |
|------------------|--------------------|------------------|--------------------|
| 0 | 100 | 8 | 1600 |
| 1 | 200 | 9 | 2000 |
| 2 | 300 | 10 | 2400 |
| 3 | 400 | 11 | 3200 |
| 4 | 600 | 12 | 4000 |
| 5 | 800 | 13 | 5200 |
| 6 | 1000 | 14 | 6400 |
| 7 | 1200 | 15 | 8000 |

13.x stands for index 1 or 2 y stands for index from 0 to 11

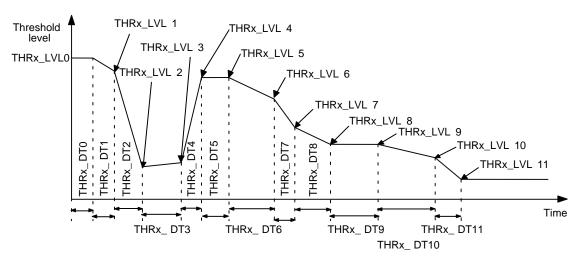


Figure 9. Threshold Curve Example

Threshold levels are piecewise approximated inside the thresholds intervals.

THR1_LVL11[5:0] resp. THR2_LVL11[5:0] threshold is applied until end of measurement if last delta time expires prior end of measurement.

NOISE_THR[5:0] is used during noise monitoring (the same threshold for both direct and indirect measurement).

Table 22. THRESHOLD TABLE DATA IN CONFIGURATION MEMORY (INDEX 5 AND 6)

(Data are transferred LSBit first)

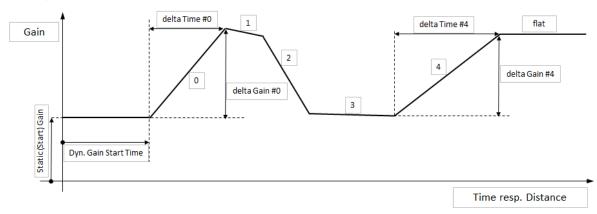
| Data Frame Byte | Data Frame Bit | Threshold Table Bit |
|-----------------|----------------|---------------------|
| 0 | 0 | THRx_LVL0 [0] |
| | | |
| | 5 | THRx_LVL0 [5] |
| | 6 | THRx_LVL3 [0] |
| | 7 | THRx_LVL3 [1] |
| 1 | 8 | THRx_LVL1 [0] |
| | | |
| | 13 | THRx_LVL1 [5] |
| | 14 | THRx_LVL3 [2] |
| | 15 | THRx_LVL3 [3] |
| 2 | 16 | THRx_LVL2 [0] |
| | | |
| | 21 | THRx_LVL2 [5] |
| | 22 | THRx_LVL3 [4] |
| | 23 | THRx_LVL3 [5] |
| | | |
| 6 | 48 | THRx_LVL8 [0] |
| | | |
| | 53 | THRx_LVL8 [5] |
| | 54 | THRx_LVL11 [0] |
| | 55 | THRx_LVL11 [1] |
| 7 | 56 | THRx_LVL9 [0] |
| | | |
| | 61 | THRx_LVL9 [5] |
| | 62 | THRx_LVL11 [2] |
| | 63 | THRx_LVL11 [3] |
| 8 | 64 | THRx_LVL10 [0] |
| | | |
| | 69 | THRx_LVL10 [5] |
| | 70 | THRx_LVL11 [4] |
| | 71 | THRx_LVL11 [5] |
| 9 | 72 | THRx_DT0 [0] |
| | | |
| | 75 | THRx_DT0 [3] |
| | 76 | THRx_DT1 [0] |
| | | |
| | 79 | THRx_DT1 [3] |
| | | |
| 14 | 112 | THRx_DT10 [0] |
| | | |
| | 115 | THRx_DT10 [3] |
| | 116 | THRx_DT11 [0] |
| | | |
| | 119 | THRx_DT11 [3] |

DYNAMIC GAIN

Dynamic gain curve principle is depicted in Figure 10. It is similar to threshold interpolation algorithm.

See Table 1 index 8 for dynamic gain parameters. Other details are depicted in Figure 10.

Dynamic Gain Curve:



Block Diagram:

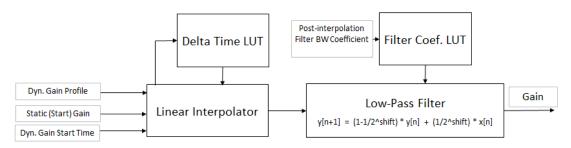


Figure 10. Dynamic Gain Principle

Table 23. DYNAMIC GAIN DELTA TIME DELTA_GAIN_DTz[3:0] CODE LUT (LOOK-UP TABLE)

| DELTA_GAIN_DTz[3:0] Code | Delta Time [μs] | DELTA_GAIN_DTz[3:0] Code | Delta Time [μs] |
|--------------------------|-----------------|--------------------------|-----------------|
| 0 | 102.4 | 8 | 3276.8 |
| 1 | 204.8 | 9 | 4505.6 |
| 2 | 409.6 | 10 | 5939.2 |
| 3 | 819.2 | 11 | 7987.2 |
| 4 | 1228.8 | 12 | 10035.2 |
| 5 | 1638.4 | 13 | 12697.6 |
| 6 | 2048 | 14 | 15974.4 |
| 7 | 2457.6 | 15 | 20070.4 |

14.z stands for index from 0 to 4

Dynamic gain curve is smoothed in low-pass filter which runs at 2.5 MHz. The filter formula is:

$$y_{n+1} = \left(1 - \frac{1}{2^s}\right) \times y_n + \frac{1}{2^s} \times x_n$$

where:

- y = output dynamic gain curve
- x = input signal from dynamic gain interpolator
- s = shift coefficient which defines filter bandwidth

Table 24. DYNAMIC GAIN FILTER COEFFICIENT DYN_GAIN_BW[1:0] CODE LUT (LOOK-UP TABLE):

| DYN_GAIN_BW[1:0] | Filter Bandwidth | Coefficient "s" |
|------------------|-------------------------|-----------------|
| 0 | No filter, pass through | 0 |
| 1 | Fast | 8 |
| 2 | Normal | 9 |
| 3 | Slow | 10 |

Dynamic Gain Start Delay

Dynamic gain curve starts at begin of measurement cycle but it is delayed by the time:

"Dyn. Gain Start Time" = DYN_GAIN_START[3:0] * 204.8 µs

The range is from 0 μ s to 3072 μ s. Equivalent approximate distance is from 0 cm to 52.2 cm.

Table 25. DYNAMIC GAIN IN CONFIGURATION MEMORY (INDEX 8) (Data are transferred LSBit first.)

| Data Frame Bit | Data Bit | | | | |
|----------------|--|--|--|--|--|
| 0 | DELTA_GAIN0 [0] | | | | |
| | | | | | |
| 6 | DELTA_GAIN0 [6] | | | | |
| 7 | DELTA_GAINO_SIGN | | | | |
| 8 | DELTA_GAIN1 [0] | | | | |
| | | | | | |
| 14 | DELTA_GAIN1 [6] | | | | |
| 15 | DELTA_GAIN1_SIGN | | | | |
| | | | | | |
| 32 | DELTA_GAIN4 [0] | | | | |
| | | | | | |
| 38 | DELTA_GAIN4 [6] | | | | |
| 39 | DELTA_GAIN4_SIGN | | | | |
| 40 | DELTA_GAIN_DT0 [0] | | | | |
| | | | | | |
| 43 | DELTA_GAIN_DT0 [3] | | | | |
| 44 | DELTA_GAIN_DT1 [0] | | | | |
| | | | | | |
| 47 | DELTA_GAIN_DT1 [3] | | | | |
| 48 | DELTA_GAIN_DT2 [0] | | | | |
| | | | | | |
| | DELTA_GAIN_DT2 [3] | | | | |
| | DELTA_GAIN_DT3 [0] | | | | |
| | | | | | |
| | DELTA_GAIN_DT3 [3] | | | | |
| 56 | DELTA_GAIN_DT4 [0] | | | | |
| | | | | | |
| 59 | DELTA_GAIN_DT4 [3] | | | | |
| 60 | DYN_GAIN_START [0] | | | | |
| | | | | | |
| | DYN_GAIN_START [3] | | | | |
| | DYN_GAIN_BW [0] | | | | |
| 65 | DYN_GAIN_BW [1] | | | | |
| | 0 66 7 8 14 15 32 38 39 40 43 44 47 48 51 55 55 56 59 60 59 63 63 64 | | | | |

15.DELTA_GAINx_SIGN = 0 ... positive DELTA_GAINx 16.DELTA_GAINx_SIGN = 1 ... negative DELTA_GAINx

SUPER READ, SUPER WRITE

Super read data transfer is very useful at ultrasonic system startup. It enables to read all configuration memory items in one transaction which are initialized from EEPROM memory at power-on reset.

Then, the communication master (ECU) can use super write data transfer to initialize most of configuration memory items.

Table 26. INDEX 11 READ DATA STRUCTURE (Data are transferred LSBit first.)

| Data Frame Byte | Data Frame Bit | Threshold Table Bit | | | |
|-----------------|----------------|--------------------------|--|--|--|
| 0 | 0 | CARRIER_PER [0] | | | |
| | | | | | |
| | 7 | CARRIER_PER [7] | | | |
| 1 | 8 | CARRIER_PER [8] | | | |
| | 9 | CARRIER_PER [9] | | | |
| | 10 | CARRIER_PER [10] | | | |
| | 11 | RX_GAIN_CODE [0] | | | |
| | | | | | |
| | 15 | RX_GAIN_CODE [4] | | | |
| 2 | 16 | RX_GAIN_CODE [5] | | | |
| | 17 | RX_GAIN_CODE [6] | | | |
| | 18 | DYN_GAIN_ENA | | | |
| | 19 | REVERB_MON_DUR [0] | | | |
| | | | | | |
| | 23 | REVERB_MON_DUR [4] | | | |
| 3 | 24 | REVERB_MON_DUR [5] | | | |
| | 25 | REVERB_MON_DUR [6] | | | |
| | 26 | REVERB_MON_DUR [7] | | | |
| | 27 | TX_CURR [0] | | | |
| | | | | | |
| | 31 | TX_CURR [4] | | | |
| 4 | 32 | TX_CURR [5] | | | |
| | 33 | REVERB_PER_VAR_LIMIT [0] | | | |
| | 34 | REVERB_PER_VAR_LIMIT [1] | | | |
| | 35 | CARRIER_PER_AUTO_ENA | | | |
| | 36 | NOISE_SUPP_ENA | | | |
| | 37 | TOF_CALIB [0] | | | |
| | 38 | TOF_CALIB [1] | | | |
| | 39 | TOF_CALIB [2] | | | |
| 5 | 40 | TOF_CALIB [3] | | | |
| | 41 | TOF_CALIB [4] | | | |
| | 42 | TOF_CALIB [5] | | | |
| | 43 | IO_PUP_ENA | | | |
| | 44 | IO_SLP_FAST | | | |

Index 11 write data structure. Data are transferred LSBit first.

It is a sequential write to the following indexes in the following order: 2a, 3, 4, 7 and 10.

COMMAND BYTE

The chip is commanded to requested action by writing the particular *Command Code* to the command byte item in configuration memory at index 15. The Command Byte cannot be read back, it is write only access. Commands are

protected by 8-bits coding, Hamming distance, checksum and number of message bits. Unwanted execution is practically impossible.

Table 27. COMAND BYTE

| Command Code | Action |
|---------------------------|--|
| hex: 29 bin: 0010 1001 | Unlock EEPROM – unlocks EEPROM for next I/O Line command. EEPROM has to be unlocked first to successfully execute Program EEPROM and Refresh Configuration RAM. EEPROM is automatically locked after the finishing of any following command. |
| hex: D6 bin: 1101 0110 | Program EEPROM – store data in configuration memory marked "Yes" in EEPROM column in Table 1 into EEPROM |
| hex: 73 bin: 0111 0011 | Refresh Configuration RAM from EEPROM (items stored in EEPROM only) |
| hex: Ax bin: 1010 xxxx | Write TP_ENA bits - TP_ENA[3:0] <= CommandByte[3:0] |
| hex: E7 bin: 1110 0111 | Unlock reading from Conf. RAM index <512> – enables reading from Conf. RAM indexes <512>, otherwise there will be no response to I/O Line read command for Conf. RAM indexes <512> |
| hex: 18 bin: 0001 1000 | Lock reading from Conf. RAM index <512> – disables reading from Conf. RAM indexes <512> |
| hex: 92 bin: 1001 0010 | Activate low power mode – The chip enters low consumption mode and it only accepts IO Line command bytes "De-activate low power mode" and "SW reset". Normal operation is not possible. |
| hex: 5 bin: 0000 0101 | De-activate low power mode – Normal mode is re-entered from low power mode and normal operation is restored. See Electrical Characteristic section for required wake time (t _{wake}) to re-enter normal mode. |
| hex: 5A bin: 0101 1010 | SW reset – Software activation of power-on reset (POR). This command effect is equal to POR. |
| others | no reaction |

^{17.} Reading from Conf. RAM indexes <5...12> is enabled after POR.

Store Data to EEPROM:

1st command *Unlock EEPROM* 2nd command *Program EEPROM*

Refresh Data from EEPROM:

1st command *Unlock EEPROM* 2nd command *Refresh Configuration RAM*

CHIP ID

The chip ID can be read from index 15. It is read only access.

Table 28. INDEX 15 DATA READ STRUCTURE (Data are transferred LSBit first.)

| Data Frame Byte | Data Frame Bit | Threshold Table Bit |
|-----------------|----------------|---------------------|
| 0 | 0 | IC_ID_MT [0] |
| | | |
| | 3 | IC_ID_MT [3] |
| | 4 | IC_ID_FM [0] |
| | | |
| | 7 | IC_ID_FM [3] |

^{18.}IC_ID_FM: Full mask silicon version. Completely modified silicon version.

^{19.} IC_ID_MT: Metal tune silicon subversion. Small bugs can be fixed by different active components interconnection. Metal layers are modified but active silicon components remain the same.

^{20.} The first silicon version is: IC_ID_FM = 1, IC_ID_MT = 1

^{21.} The second silicon version is: IC_ID_FM = 2, IC_ID_MT = 1

CUSTOMER TEST OUTPUTS, TP_ENA

Custom diagnostic test (debugging) output/input (TST1...4) signals are selected by TP_ENA bits. TP_ENA bits are set via appropriate Command byte. DSP internal

"analog" signals are PDM modulated. External low-pass filters are required. See table below for valid test signal combinations.

Table 29. CUSTOMER TEST OUTPUTS, TP_ENA

| TP_ENA[3:0] | TST0 | TST1 | TST2 | TST3 |
|-------------------|----------------------------------|--|------------------------|-----------------------|
| 0000 (Default) | Hi–Z / 4 kΩ | Hi–Z / 4 kΩ | Hi–Z / 4 kΩ | Hi–Z / 4 kΩ |
| 0001 | Hi–Z / 4 kΩ | Hi–Z / 4 kΩ | THRESHOLD[9:0] PDM2 | ECHO_MAG[9:0] PDM1 |
| 0010 | Hi–Z / 4 kΩ | Hi–Z / 4 kΩ | ECHO_ENVELOPE PDM2 | ECHO_MAG[9:0] PDM1 |
| 0011 | Hi–Z / 4 kΩ | Hi–Z / 4 kΩ | Not Defined | Not Defined |
| 0100 | Hi–Z / 4 kΩ | Hi–Z / 4 kΩ | ECHO_DET | ECHO_MAG[9:0] PDM1 |
| 0101 | Hi–Z / 4 kΩ | Hi–Z / 4 kΩ | Not Defined | Not Defined |
| 0110 | Hi–Z / 4 kΩ | Hi–Z / 4 kΩ | GAIN[7:0] PDM2 | ECHO_MAG[9:0] PDM1 |
| 0111 | Hi–Z / 4 kΩ | Hi–Z / 4 kΩ | IO_RXD | IO_DRV (input) |
| 1000 | Single Ended Analog RX Output | Permanent Digital Output Set to "1" | Hi–Z / 4kΩ | Hi–Z / 4kΩ |
| 1001 | Single Ended Analog RX Output | Permanent Digital Output Set to "1" | THRESHOLD[9:0] PDM2 | ECHO_MAG[9:0] PDM1 |
| 1010 | Single Ended Analog RX Output | Permanent Digital Output Set to "1" | ECHO_ENVELOPE PDM2 | ECHO_MAG[9:0] PDM1 |
| 1011 | Single Ended Analog RX Output | Permanent Digital Output Set to "1" | Not Defined | Not Defined |
| 1100 | Single Ended Analog RX Output | Permanent Digital Output Set to "1" | ECHO_DET | ECHO_MAG[9:0] PDM1 |
| 1101 | Single Ended Analog RX Output | Permanent Digital Output Set to "1" | Not Defined | Not Defined |
| 1110 | Single Ended Analog RX Output | Permanent Digital Output Set to "1" | GAIN[7:0] PDM2 | ECHO_MAG[9:0] PDM1 |
| 1111 | Single Ended Analog RX Output | Permanent Digital Output Set to "1" | IO_RXD | IO_DRV (Input) |

- 22. Hi–Z / 4 k Ω = IO is not driven but pull down active
- 23. VGA_Gain = (analog(PDM2) / 20 mV) * (30 / 63) dB
- 24. Initial/POR value shall be 0 decimal ("0000" binary) test outputs are disabled 25. GAIN[7:0] is effectively using half of the full-scale of PDM output
- 26. Threshold[9:0] is effectively using half of the full-scale of PDM output

Recommended External Low-pass Filter

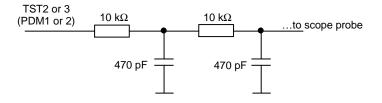


Figure 11. Recommended PDM External Low-pass Filter

EEPROM PROGRAMMING SEQUENCE

EEPROM programming operation is performed in 12 successive steps:

- 1. Power-on the device.
- Read Configuration RAM index 1 to clear SENSOR_STATUS (SENSOR_STATUS[7] = HW ERROR).
- 3. Write data into Configuration RAM (EEPROM shadow registers).
- 4. Verify EEPRPOM shadow registers content by reading back Configuration RAM index 11 (super read) and index 9. If mismatch detected, go-to step 2.
- 5. Unlock EEPROM Write Command Code 0x29hex into Configuration RAM index 15.
- 6. Program EEPROM Write Command Code 0xD6hex into Configuration RAM index 15.

- 7. Wait 25 ms. It is needed to complete programming of the EEPROM memory.
- 8. Unlock EEPROM Write Command Code 0x29hex into Configuration RAM index 15.
- 9. Refresh Configuration RAM Write Command Code 0x73hex into Configuration RAM index 15.
- 10. Read Configuration RAM index 1 to get SENSOR_STATUS. SENSOR_STATUS[7] (EEPROM ERROR or HW_ERROR) should be 0. If SENSOR_STATUS[7] is 1, EEPROM failure occurred, then, go-to step 3.
- 11. Verify EEPRPOM shadow registers content by reading back Configuration RAM index 11 (super read) and index 9. If mismatch detected, go-to step 3
- 12. Power-off the device.

EEPROM ERROR CORRECTION BLOCK

The error correction block utilizes SECDED coding for one bit error correction and 2 bits error detection. As data are split in words 16 bits long each, 5 extra bits are required for encoding ECC (Hamming code) and one extra bit for parity check (two bits error detection). The encoding bits are spread into the bit matrix accordingly to the Tab.2.

| Bit | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 | 12 | 13 | 14 | 15 | 16 | 17 | 18 | 19 | 20 | 21 |
|------|----|----|----|----|----|----|----|----|----|----|----|----|----|----|-----|----|-----|-----|-----|-----|-----|
| Data | P0 | P1 | D0 | P2 | D1 | D2 | D3 | P3 | D4 | D5 | D6 | D7 | D8 | D9 | D10 | P4 | D11 | D12 | D13 | D14 | D15 |
| P0 | X | | X | | X | | х | | X | | X | | X | | X | | х | | X | | X |
| P1 | | Х | Х | | | X | х | | | Х | Х | | | X | X | | | X | X | | |
| P2 | | | | X | X | X | х | | | | | Х | X | X | X | | | | | X | X |
| P3 | | | | | | | | х | х | Х | х | х | х | х | Х | | | | | | |
| P4 | | | | | | | | | | | | | | | | х | Х | X | X | Х | х |

Figure 12. 16-bits Word SECDED Encoding

Error correction is based on the calculation of the parity bits. The parity bits are spread in such a way, that if the parity fails, the position of the error bit is defined directly by the position of the failing bits.

Example 1:

If the failure appears on bit 9 (D4), the parity of P0 and P3 will be wrong (column for bit 9, X's are for P0 and P3). Putting one on the wrong positions of the parity when writing parity word would be:

P4, P3, P2, P1, P0 = 01001 binary = 9 decimal.

Example 2:

Error is on parity bit P4 – the word is 10000 = bit 16 decimal (that is directly the parity bit P4).

If two bits error is detected, invalid data of the impacted address in the shadow registers will not be updated.

IO_LINE_CTRL (COMMAND PULSE, MEASUREMENT CONTROL, DATA COMMUNICATION)

I/O Line is a master-slave point-to-point communication link. If more than one chip is connected to master (ECU) unit, it creates **star topology**.

Every I/O Line communication starts with particular command pulse. Its length and meaning is in table below:

Table 30. IO_LINE COMMAND PULSE

| Command Pulse | Min. Pulse Length [μs]* | Typ. Pulse Length [μs] | Max. Pulse Length [μs]* | Addressing | Description |
|-------------------|----------------------------|---------------------------|----------------------------|------------|--|
| T _{SND1} | 328 | 400 | 472 | - | TX+RX (direct measurement with THR1 table) |
| T _{REC2} | 503 | 580 | 657 | - | RX only (indirect measurement with THR2 table) |
| T _{REC1} | 697 | 780 | 863 | - | RX only (indirect measurement with THR1 table) |
| T _{SND2} | 920 | 1010 | 1100 | - | TX+RX (direct measurement with THR2 table) |
| T _{DATA} | 1172 | 1270 | 1368 | R/nW, xxxx | Data communication |

^{*}I/O Line command pulse, which is generated by ECU master, has to be always in range from minimal pulse length to maximal pulse length under any applicable condition (especially EMC disturbance, which may shift I/O Line edges by tens of microseconds). It is strongly recommended to generate command pulses as close as possible to typical pulse length to keep maximal command recognition margin.

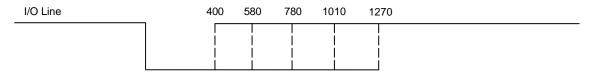


Figure 13. I/O Line Command Pulses

IO LINE SHORT TO VBAT/GND DETECTION

If the chip detects that I/O Line logical value (dominant or recessive level) differs from the value driven by the chip for time $\geq 350~\mu s$ then I/O Line short circuit condition is detected. In this case, the chip immediately stops driving the I/O Line.

On-going measurement respective I/O Line data communication is immediately interrupted. I/O Line has to be in recessive level for at least T_{DEB} time to accept the next I/O Line command.

MEASUREMENT CONTROL

The measurement can be started by T_{SND1} , T_{REC2} , T_{REC1} or T_{SND2} command pulse. Measured ultrasonic echoes can be reported on I/O Line in 3 different modes. Modes are

selected in Configuration Memory. The figure below depicts these modes.

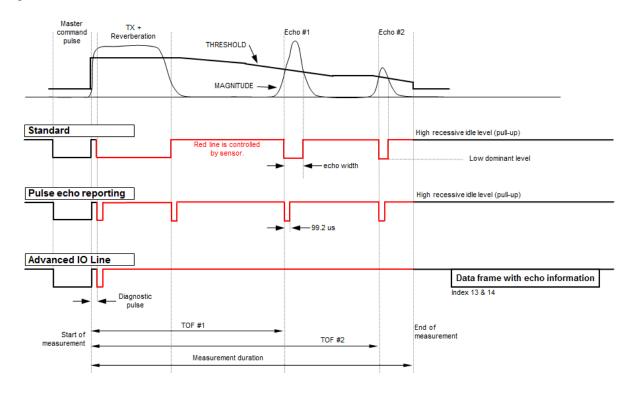


Figure 14. I/O Line Measurement Modes Comparison

Table 31. I/O LINE MEASUREMENT MODES COMPARISON

| Measurement IO Line Mode | Diagnostic Pulse IO_TRANS_DIAG_ENA | Echo IO Line Reporting | Echo Width Information | Measurement Can be Stopped | | |
|---|--|--|---------------------------|---|--|--|
| Standard Yes (optional) | | Dominant pulse | Yes | No | | |
| Pulse Echo Reporting IO_ECHO_PULSE_ENA = 1 ADV_IO_ENA = 0 | Yes (optional) | Dominant pulse of 99,2 μs | No | Yesby at least 350 μs dominant pulse which is generated by the I/O Line master. | | |
| Advanced IO Line IO_ECHO_PULSE_ENA = 0 ADV_IO_ENA = 1 | Yes (always, it is used for acknowledge) | IO Line is idle during measurement => No Disturbance Echoes times are reported in configuration memory index 13 and 14. | No | Yesby 100 μs dominant pulse or any command pulse which is generated by the I/O Line master. | | |

T_{SND1}/T_{SND2} Command (Direct Measurement); ADV_IO_ENA = 0

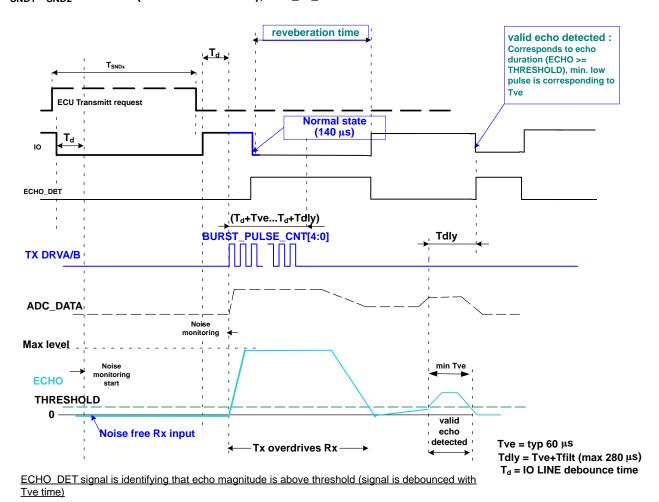


Figure 15. Send Command Sequence with Threshold Table 1 (T_{SND1}) and Threshold Table 2 (T_{SND2})

Noise Free and Defect Free Case

T_{SND1}/T_{SND2} Command (Direct Measurement); ADV_IO_ENA = 1

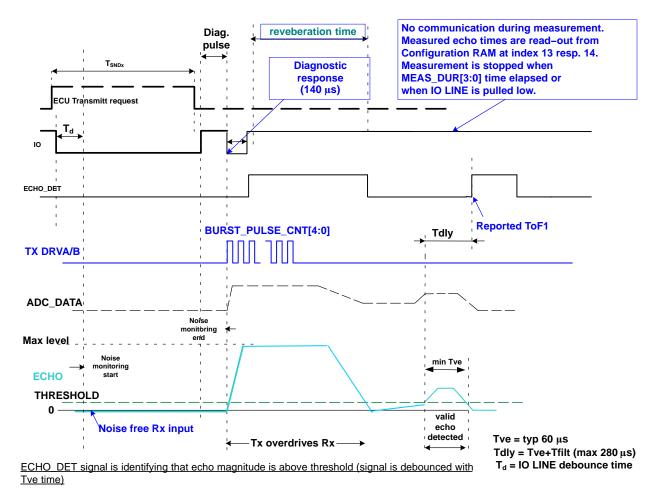
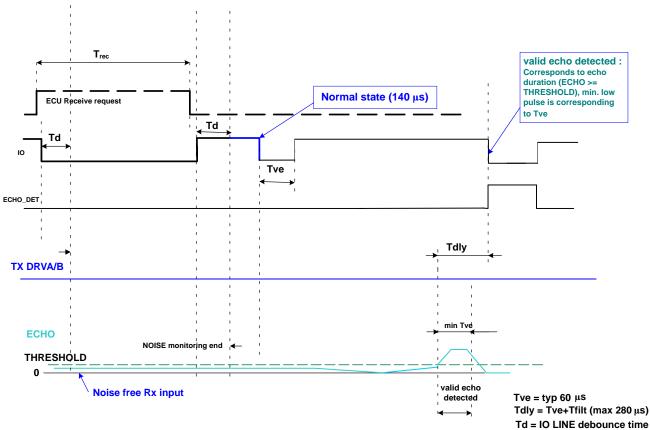


Figure 16. Send Command Sequence with Threshold Table 1 (T_{SND1}) and Threshold Table 2 (T_{SND2})

Noise Free and Defect Free Case

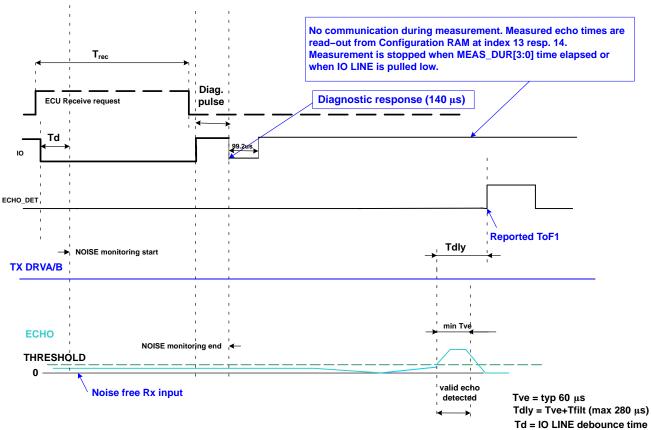
 T_{REC1}/T_{REC2} Command (Indirect Measurement); ADV_IO_ENA = 0



ECHO_DET signal is identifying that echo magnitude is above threshold (signal is debounced with Tve time)

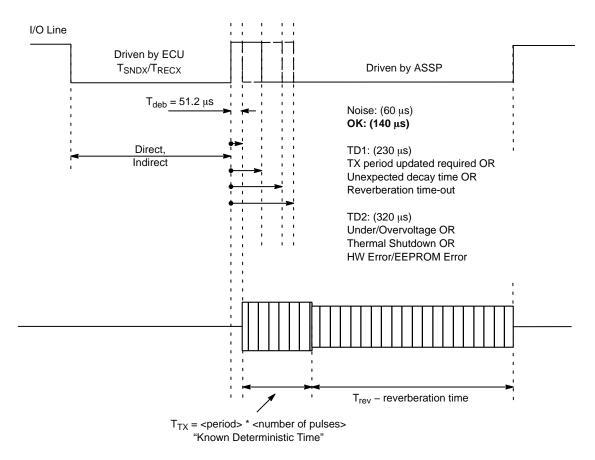
Figure 17. Receive Command Sequence Noise Free and Defect Free Case

T_{REC1}/T_{REC2} Command (Indirect Measurement); ADV_IO_ENA = 1



ECHO_DET signal is identifying that echo magnitude is above threshold (signal is debounced with Tve time)

Figure 18. Receive Command Sequence Noise Free and Defect Free Case



Note: All NCV75215 generated timing has accuracy of 3%.

Figure 19. I/O Line Noise Reporting and Sensor Defect Reporting (Diagnostic Pulse) for T_{SNDx} and T_{RECx} Commands

DATA COMMUNICATION

Every I/O Line data communication starts by T_{DATA} command pulse. The chip supports index data read and write transfers.

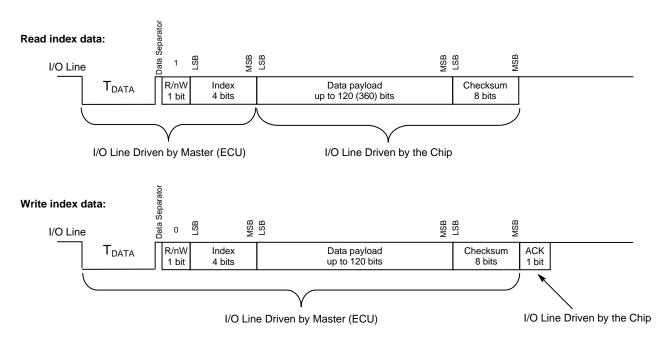


Figure 20. Read and Write Index Data

Table 32. I/O LINE DATA COMMUNICATIONS COMMAND

| Command Part | No. of Bits | Typical Time [μs] | Note |
|---------------------------------|-------------|-------------------|---------------------------|
| Command pulse T _{DATA} | _ | 1270 | I/O Line low |
| Data separator* | _ | 100 | I/O Line high (idle) |
| R/nW bit | 1 | 300 | 0 write operation, 1 read |
| Configuration memory index | 4 | 1200 | 4 address bits |
| Data payload | х | 300 * x | x number of bits |
| Enhanced check sum | 8 | 2400 | |
| Acknowledge bit | (1) | (300) | Write operation only |
| Command separator | _ | > 100 | I/O Line high (idle) |

^{*}When reception of data separator is finished (identified by I/O Line falling edge of R/nW bit) temperature measurement is executed. Typical duration of temperature measurement is 10 µs.

Total data write command time in [µs]:

 $T_{DATA}(DATA_WRITE) = 5670 + 300 * < number of data payload bits>$

Every data bit is modulated as I/O Line PWM pulse according to the Figure 21.

The ECU should drive I/O Line low for t_{typ} [μ s] ($T_{BIT_LOW} = 1/3 * T_{BIT}$, $T_{BIT_HIGH} = 2/3 * T_{BIT}$, where $T_{BIT} = 300~\mu$ s).

Data rate is accepted from 2.7 kbit/s to 4.4 kbit/s (typically 3.3 kbit/s).

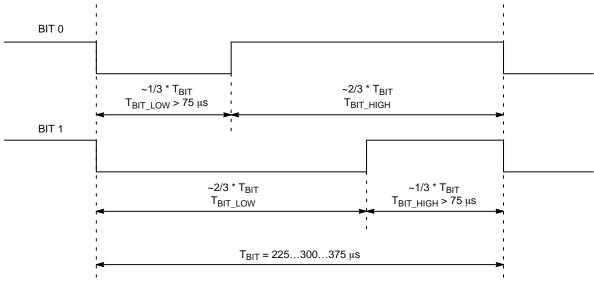


Figure 21. BIT0/BIT1 Coding

Meaning of R/nW + Address bits and overview of Configuration Memory indexes is in table below:

Table 33.

| Addressing: R/nW + 4 Index Address Bits | Config Memory Index | Configuration Memory Index Description |
|--|---------------------|--|
| R 0000 | 0 | Temperature |
| R 0001 | 1 | Status byte + Reverberation period |
| R/nW 0010 | 2 | Carrier Period |
| R/nW 0011 | 3 | TX burst pulse count |
| R/nW 0100 | 4 | Measurement duration |
| R/nW 0101 | 5 | Threshold table #1 |
| R/nW 0110 | 6 | Threshold table #2 |
| R/nW 0111 | 7 | Gain + Noise measurement setting |
| R/nW 1000 | 8 | Dynamic gain |
| R/nW 1001 | 9 | User data |
| R/nW 1010 | 10 | Reverberation + TX current + other setting |
| R/nW 1011 | 11 | Super read / write |
| R 1100 | 12 | Measurement echo magnitude data (sampled echo magnitude) |
| R 1101 | 13 | Measurement results – short |
| R 1110 | 14 | Measurement results – long |
| R/nW 1111 | 15 | Command Byte/Chip ID |

CHECKSUM

Validity of data transferred over I/O Line is ensured by Enhanced 8-bit Checksum. The checksum calculation is explained in example below.

Example:

R/nW = 1 (read operation)

Index = 2 = 0010 bin

CARRIER_PER [10:0] = 3EA hex

11 data payload bits => 2 bytes for checksum calculation

1. 8-bit Checksum Initial Value

| Bit | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|----------------|------|-------------|-------------|-------------|-------------|---|---|---|
| Data | R/nW | Index bit 3 | Index bit 2 | Index bit 1 | Index bit 0 | 0 | 0 | 0 |
| Example = 0x90 | 1 | 0 | 0 | 1 | 0 | 0 | 0 | 0 |

2. Data

| Byte | Bit 7 | Bit 6 | Bit 5 | Bit 4 | Bit 3 | Bit 2 | Bit 1 | Bit 0 |
|---------------------|------------------|----------------|----------------|----------------|----------------|-------|-------|-------|
| 0 Example = 0xEA | CP7 (Note 28) | CP6 | CP5 | CP4 | CP3 | CP2 | CP1 | CP0 |
| | 1 | 1 | 1 | 0 | 1 | 0 | 1 | 0 |
| 1 Example = 0x03 | 0 (Note 27) | 0 (Note 27) | 0 (Note 27) | 0 (Note 27) | 0 (Note 27) | CP10 | CP9 | CP8 |
| | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 1 |

^{27.} Incomplete byte is padded by 0 s. 28. "CP" stands for CARRIER_PER.

3. Checksum Calculation

Algorithm:

```
unsigned int check sum =
             (RnW \ll 7) \mid (index \ll 3);
for (i=0; i<byte count; i++)
    { check sum = check sum + data byte[i];
      if (check sum > 255)
          check sum = check sum - 255;
check sum = check sum ^ 0xFF;
```

Example:

 $check_sum = 0x90$ (initial value in this example)

byte #0:

 $check_sum = 0x90 + 0xEA = 0x17A$

 $check_sum = 0x17A - 0xFF = 0x7B$

byte #1:

 $check_sum = 0x7B + 0x03 = 0x7E$

4. Checksum Inversion

check sum = 0x7E xor 0xFF = 0x81

Checksum to transmit is inversion of final checksum accumulator (not $0x7E \Rightarrow 0x81$ to transmit/check as checksum).

ACKNOWLEDGE BIT

Meaning of Acknowledge bit is explained in Figure 22.

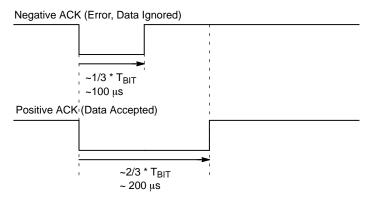
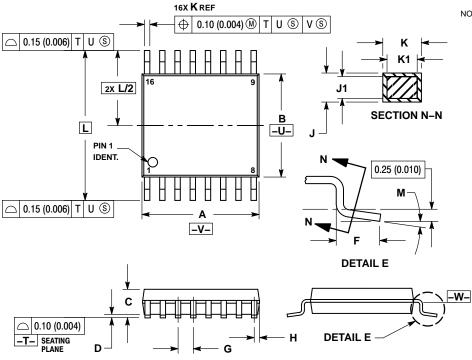


Figure 22. I/O Data Communication - Meaning of Acknowledge Bit

The chip transmits acknowledge bit after reception of the last checksum bit. Acknowledge bit is transmitted after data write transfer only.

PACKAGE DIMENSIONS

TSSOP-16 CASE 948F **ISSUE B**



NOTES:

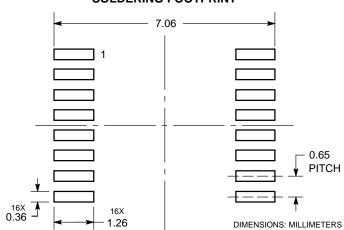
- DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETER.
- 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
 5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION. CONDITION.

 6. TERMINAL NUMBERS ARE SHOWN FOR
- REFERENCE ONLY.

 7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

| | MILLIN | IETERS | INCHES | | |
|-----|--------|--------|-----------|-------|--|
| DIM | MIN | MAX | MIN | MAX | |
| Α | 4.90 | 5.10 | 0.193 | 0.200 | |
| В | 4.30 | 4.50 | 0.169 | 0.177 | |
| C | | 1.20 | | 0.047 | |
| D | 0.05 | 0.15 | 0.002 | 0.006 | |
| F | 0.50 | 0.75 | 0.020 | 0.030 | |
| G | 0.65 | BSC | 0.026 BSC | | |
| Н | 0.18 | 0.28 | 0.007 | 0.011 | |
| J | 0.09 | 0.20 | 0.004 | 0.008 | |
| J1 | 0.09 | 0.16 | 0.004 | 0.006 | |
| K | 0.19 | 0.30 | 0.007 | 0.012 | |
| K1 | 0.19 | 0.25 | 0.007 | 0.010 | |
| ٦ | 6.40 | BSC | 0.252 BSC | | |
| М | 0° | 8° | 0° | 8 ° | |





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